# OICOM

# SERVICE MANUAL

FM TR/		IVER	T	
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Icom Inc.

### INTRODUCTION

This service manual describes the latest service information for the IC-U16T UHF FM TRANSCEIVER at the time of going to press.

Four versions of the IC-U16T have been designed. This service manual covers following versions.

VERSION	FREQUENCY RANGE (MHz)	CHANNEL SPACING (kHz)	5-TONE SYSTEM	IF BAND WIDTH
#01	460~470	12.5	CCIR	Narrow
#02	460~470	25	CCIR	Wide
#03	450~460	12.5	CCIR	Narrow
#04	450~460	25	CCIR	Wide

### DANGER

**NEVER** connect the transceiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the transceiver.

DO NOT expose the transceiver to rain, snow or any liquids.

DO NOT reverse the polarities of the power supply when connecting the transceiver.

**DO NOT** apply an RF signal of more than 20 dBm (100 mW) to the antenna connector. This could damage the transceiver's front end.

### ORDERING PARTS

Be sure to include the following four points when ordering replacement parts:

- 1. Component part number and name
- 2. Equipment model name and unit name
- 3. 10-digit order numbers for mechanical parts
- 4. Quantity required

### <SAMPLE ORDER>

IC NJM4560DD IC-U16T MAIN UNIT 5 pieces Screw PH A0 2 × 15 ZK IC-U16T Rear panel 8810000740 10 pieces

Addresses are provided on the inside back cover for your convenience.

### REPAIR NOTE

- Make sure a problem is internal before disassembling the transceiver.
- DO NOT open the transceiver until the transceiver is disconnected from a power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts. An insulated tuning tool MUST be used for all adjustments.
- 5. DO NOT keep power ON for a long time when the transceiver is defective.
- DO NOT transmit power into a signal generator or a sweep generator.
- ALWAYS connect a 30 dB ~ 40 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- READ the instructions of test equipment thoroughly before connecting equipment to the transceiver.



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To program the operating frequency, tone frequency, etc., see the separately available PROGRAMMING MANUAL (A-0876).

## SECTION 1 SPECIFICATIONS

#### GENERAL

Frequency coverage :  $450 \text{ MHz} \sim 470 \text{ MHz}$ Antenna impedance :  $50 \Omega$  unbalanced

Audio output impedance :  $8 \Omega$ 

Usable temperature range :  $-25 \,^{\circ}\text{C} \sim +60 \,^{\circ}\text{C} \, (-13 \,^{\circ}\text{F} \sim +140 \,^{\circ}\text{F})$ 

Frequency tolerance :  $\pm 0.0005 \% (-25 \degree C \sim +60 \degree C, -13 \degree F \sim +140 \degree F)$ 

 $\pm 0.0003$  % (-10 °C ~ +55 °C, +14 °F ~ +131 °F)

Current drain (at 8.4 V) : Receive standby 105 mA

Receive Max. audio 260 mA

Transmit High 1.9 A (at 13.2 V)

Low 1 A

Power supply requirement :

BATTERY PACK	VOLTAGE
CM-7	13.2 V
CM-8	8.4 V

(negative ground)

Dimensions :  $65(W) \times 196(H) \times 38(D)$  mm,  $2.6(W) \times 7.7(H) \times 1.5(D)$  in. (Projections not included)

Weight : 390 g (without battery pack)

5-Tone specification : CCIR

### **TRANSMITTER**

Output power : HIGH 5 W (with CM-7) 2.5 W (with CM-8)

LOW 1 W (with CM-7 or CM-8)

Emission mode : 16K0F3E (Wide-type)

8K50F3E (Narrow-type)

Limiting of modulator :  $70 \% \sim 100 \%$  of max. deviation

Max. frequency deviation : ±5 kHz (Wide-type) ±2.5 kHz (Narrow-type)

Audio frequency response :  $+1 dB \sim -3 dB$  with 6 dB/octave

between 300 Hz ~ 3000 Hz (Wide-type) between 300 Hz ~ 2550 Hz (Narrow-type)

Audio harmonic distortion : 10 % max.

Noise and hum ratio : 40 dB

Adjacent channel power : 70 dB (Wide-type) 60 dB (Narrow-type)

#### RECEIVER

Receiving system : Double-conversion superheterodyne

Intermediate frequencies : 1st 30.875 MHz

2nd 455 kHz

Intermodulation : 70 dB

Sensitivity : 0.35 µV for 12 dB SINAD

Squelch sensitivity (threshold) :  $0.3 \mu V$ 

Audio output power : 0.5 W at 10 % distortion with an 8  $\Omega$  load Adjacent channel selectivity : 70 dB (Wide-type) 60 dB (Narrow-type)

Spurious response rejection : 70 dB Blocking and desensitization : 90 dBµ

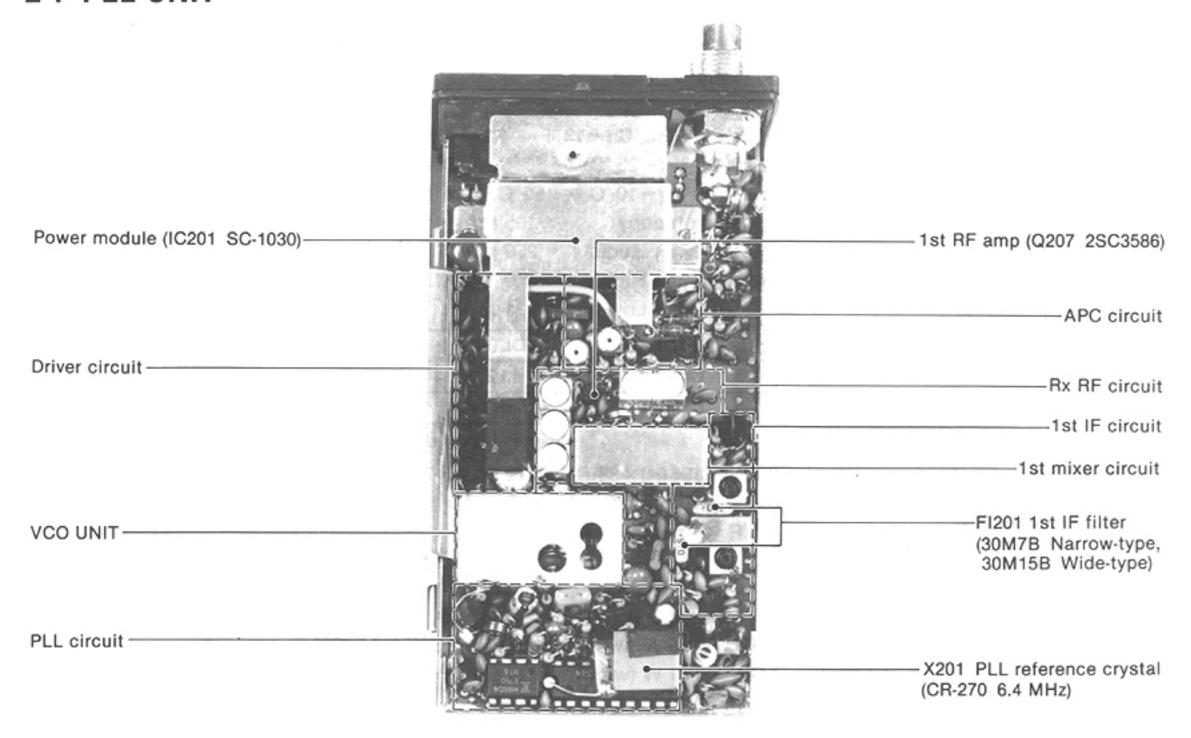
Audio frequency response :  $+1 dB \sim -3 dB$  with -6 dB/octave

between 300 Hz ~ 3000 Hz (Wide-type) between 300 Hz ~ 2550 Hz (Narrow-type)

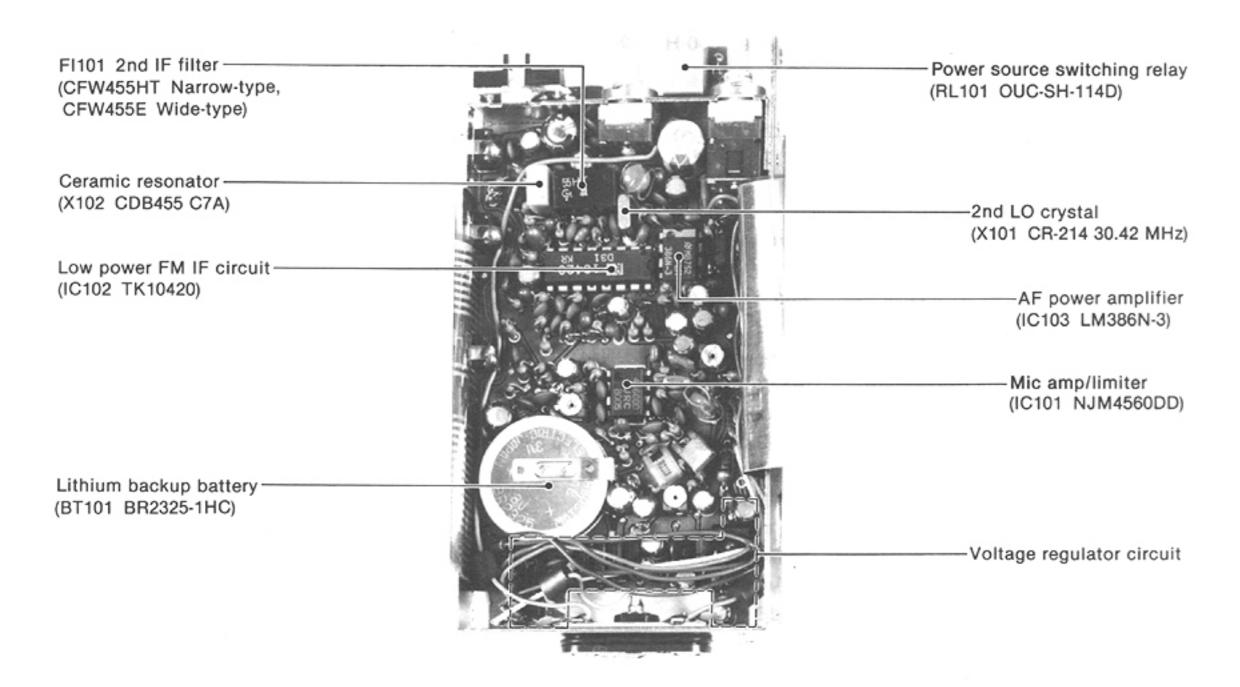
Noise and hum ratio : 40 dB

# SECTION 2 INSIDE VIEWS

# 2-1 PLL UNIT



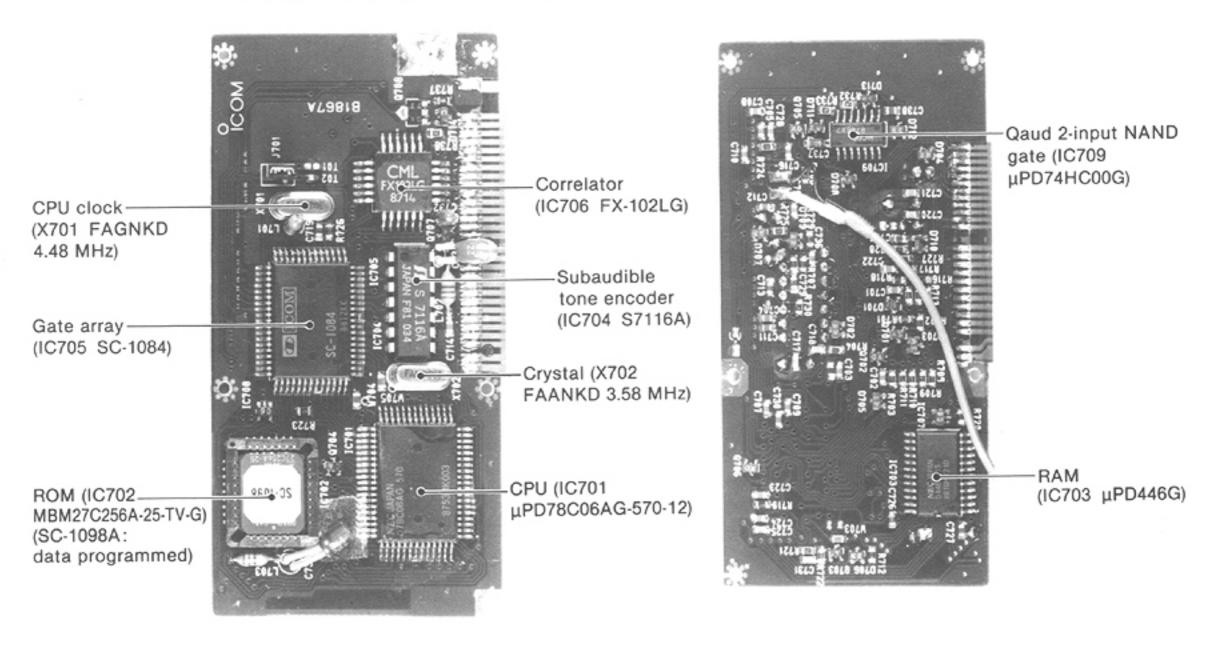
# 2-2 MAIN UNIT



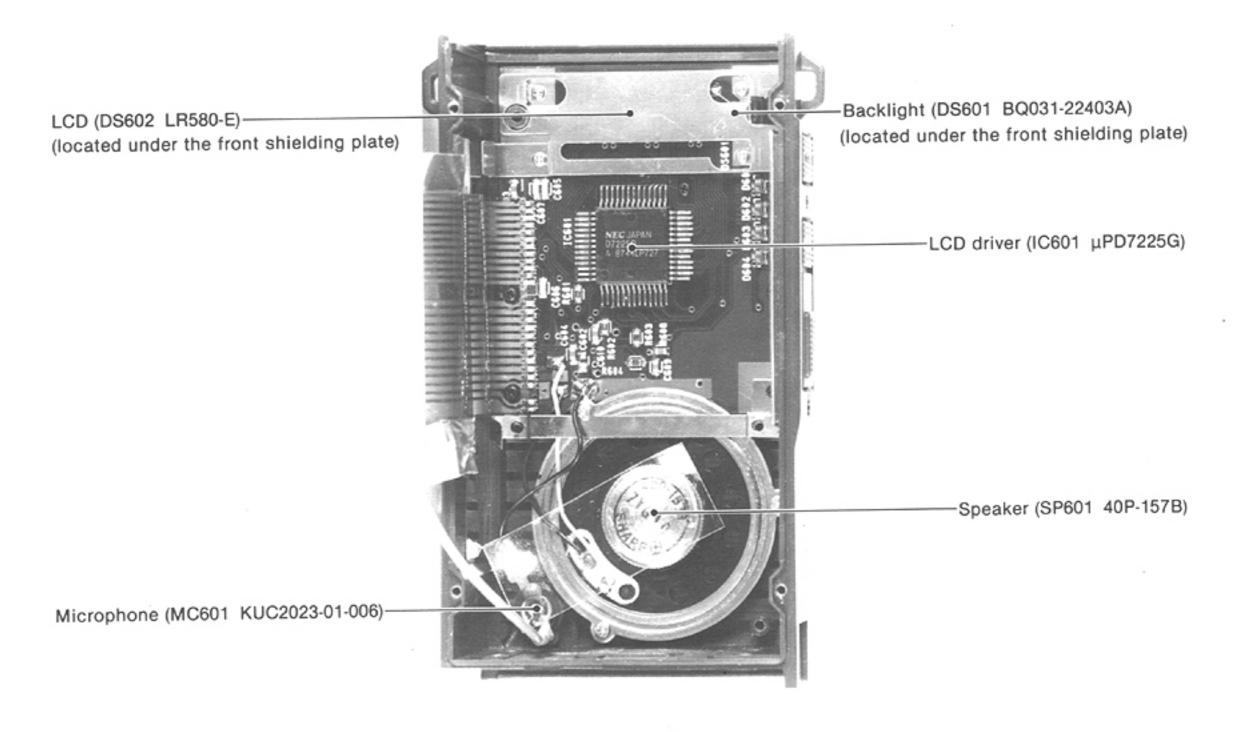
# 2-3 LOGIC UNIT

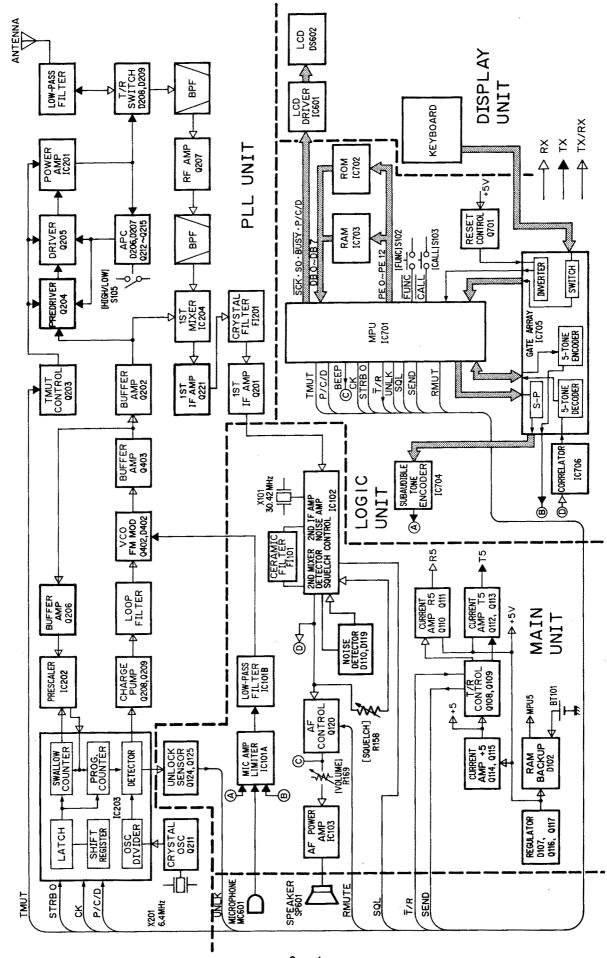
# • COMPONENT SIDE

## • FOIL SIDE



# 2-4 DISPLAY UNIT





### SECTION 4 CIRCUIT DESCRIPTION

### 4-1 RECEIVER CIRCUITS

# 4-1-1 ANTENNA SWITCHING CIRCUIT (PLL UNIT)

Receive signals enter from the antenna connector and pass through a Chebyshev low-pass filter consisting of L211, L212 and C243 $\sim$ C245. The antenna switching circuit (D208, D209, L209, C309 and C246) employs a  $\lambda/4$ -type diode switching system.

### 4-1-2 RF CIRCUIT (PLL UNIT)

The receive signal from the antenna switching circuit passes through helical bandpass filter L217 and is then amplified at the RF amplifier (Q207). Amplified signals pass through the helical bandpass filter (L219). These bandpass filters remove out-of-band signals.

The filtered signals are mixed with the 1st LO signal at the 1st mixer (IC204) to convert to a 30.875 MHz 1st IF signal. The 1st LO signal is the generating signal in the PLL circuit. Refer to Section 4-3 PLL CIRCUITS.

### 4-1-3 IF CIRCUIT (PLL AND MAIN UNITS)

The 1st IF signal from the 1st mixer is amplified at Q221, passed through crystal filter FI201 and amplified again at Q201. The amplified signal is then applied to the FM IF IC chip (IC102) in the MAIN UNIT.

IC102 contains the oscillator, mixer, limiter amplifier, quadrature detector and trigger circuits. The 1st IF signal from the PLL UNIT enters IC102 pin 16. The signal is mixed with the 2nd LO signal at the mixer section to convert to a 455 kHz 2nd IF signal.

The 2nd IF signal is output from pin 3 and passes through FI101 to remove unwanted heterodyne signals. The filtered signal re-enters at pin 5 and is then amplified at the limiter amplifier section. The amplified signal is detected at the quadrature detector section using ceramic resonator X102 to convert to an audio signal.

### 4-1-4 AF CIRCUIT (MAIN UNIT)

The audio signals output from IC102 pin 9 de-emphasize audio high frequency components at the de-emphasis circuit (R157, C151). The de-emphasis circuit has -6 dB/octave frequency characteristics.

The de-emphasized signals are amplified at Q118, pass through the audio switch (Q120) and volume control (R169) and are then applied to the audio power amplifier (IC103). IC103 drives the speaker to an AF output of more than 500 mW with an 8  $\Omega$  load.

### 4-1-5 SQUELCH CIRCUIT (MAIN UNIT)

The squelch circuit mutes the audio noise when no RF signal is received.

A portion of the audio signals output from IC102 pin 9 is picked up through C152. The signals pass through the squelch control (R158) and are applied to the operational amplifier section in IC102 (pin 10). The operational amplifier is activated as an active filter that amplifies noise components of higher than approximately 20 kHz.

The amplified noise signals output from pin 11 are detected at D110 and D119 to convert to a DC signal. When the RF signal is not received, noise components increase and then a detected DC signal also increases. This DC voltage drives the squelch trigger circuit in IC102. After being output from pin 13, the "SQL" signal ("HIGH" when the squelch is closed) is input to the CPU (IC701) at pin 15.

When the CPU receives a "HIGH" signal, the "RMUT" signal is output from pin 30, cutting off the audio switch (Q120). CPU pin 30 is also controlled by 5-Tone signals. Refer to Section 4-1-6.

### IF CIRCUIT

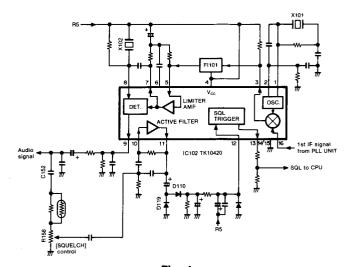


Fig. 1

### 4-1-6 5-TONE DECODER (LOGIC UNIT)

The 5-tone decoder circuit detects whether the received 5-tone code is the same as the programmed code or not, and controls the squelch circuit using the "RMUT" line.

A portion of the detected signals output from pin 9 of IC102 is applied to the auto-correlator (IC706) in the LOGIC UNIT. IC706 picks up only 5-Tone signals and eliminates noise components.

The picked up 5-Tone signals are applied to the 5-Tone Gate Array IC chip (IC705) pin 21. IC705 converts the 5-Tone signal to a hexadecimal code and sends the code to the CPU (IC701). IC701 compares the received code and programmed code. If these are same number, the "RMUT" terminal (pin 30) becomes "LOW" and opens the squelch circuit.

### **4-2 TRANSMITTER CIRCUITS**

# 4-2-1 MICROPHONE AMPLIFIER CIRCUIT (MAIN UNIT)

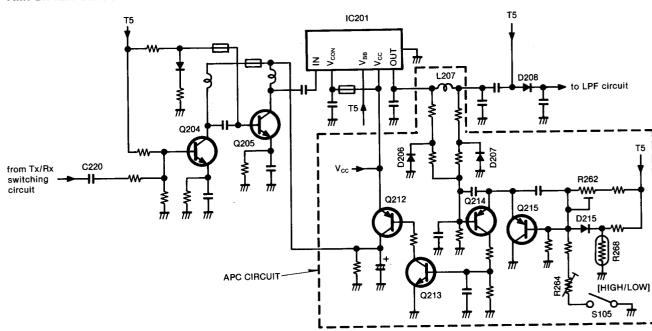
Microphone signals are amplified at IC101A. C109 and R112 are connected to IC101A pin 2 and preemphasize the microphone signal. The signal passes through a splatter filter consisting of R117, R123, R124, C115, C116 and C118 for removing noise components higher than 3 kHz.

The filtered signals are amplified at the limiter amplifier (IC101B) and are then applied to the VCO circuit in the PLL UNIT.

#### **4-2-2 MODULATION CIRCUIT (PLL UNIT)**

The amplified microphone signals are applied to the anode of D402. By applying audio signals, the capacitance of D402 is changed. Hence, the oscillating signal in the VCO is modulated.

#### RF AMPLIFIER CIRCUIT



### 4-2-3 RF AMPLIFIER CIRCUIT (PLL UNIT)

The modulated signal output from the VCO is buffer amplified at Q403 and Q202. The amplified signal then passes through the Tx/Rx switching circuit (D204). The signal is amplified at the predriver (Q204) and the driver (Q205) to obtain drive power of 150 mW.

Drive power is amplified at power module IC201 to obtain 5 W of output power. Power amplified signals pass through the APC detector circuit (L207, D206, D207), antenna switching circuit (D208, D209) and low-pass filter (L211, L212, C243~C245) and are then applied to the antenna connector.

### 4-2-4 APC CIRCUIT (PLL UNIT)

The APC (Auto Power Control) circuit protects the power module from a mismatching output load and selects HIGH or LOW output power.

The output power level from the power module (IC201) is detected at the APC detector circuit (L207, D206, D207). When antenna impedance is matched at 50  $\Omega$ , the detected level is at a minimum. However, when antenna impedance is mismatched, the detected voltage is higher than when matched.

When the antenna impedance is mismatched, the base voltage of Q214 is higher than the base voltage of Q215 (reference voltage). Q214 decreases the collector current of Q212 using Q213. Q212 collector current is used at the predriver (Q204) and the driver (Q205). Hence, when the antenna impedance is mismatched, output power is decreased.

The output power selecting circuit uses the APC circuit. The [HIGH/LOW] switch on the top panel selects the reference voltage, changing output power to HIGH or LOW.

### 4-2-5 TX MUTE CIRCUIT (PLL UNIT)

When the "TMUT" signal from CPU (IC701) pin 31 on the LOGIC UNIT is "HIGH," Q203 turns OFF to cut off the bias voltages of the predriver and driver; transmit power is then suppressed.

#### 4-3 PLL CIRCUITS

#### 4-3-1 GENERAL

The PLL circuit, using a dual modulus prescaler (IC202, IC203), generates the desired frequency at the VCO circuit. The dual modulus prescaler sets the dividing ratio based on serial data from the CPU (IC701) on the LOGIC UNIT, and compares the phases of the VCO output and the reference oscillator frequency.

The phase detected signal is converted to a lock voltage at a loop filter. The lock voltage controls the VCO oscillating frequency. Thus, a stable oscillation is obtained.

# 4-3-2 REFERENCE OSCILLATOR CIRCUIT (PLL UNIT)

Q211 and X201 oscillates a 6.4 MHz signal. The signal is divided in the divider inside IC203 to obtain a 12.5 kHz reference frequency. R246 and R247 are thermistors designed to compensate for the frequency drift of a temperature.

# 4-3-3 CHARGE PUMP AND LOOP FILTER CIRCUITS (PLL UNIT)

Phase detected signals output from IC203 pins 12 and 13 are pulse signals. These signals are converted to a DC voltage by the charge pump (Q208, Q209) and the loop filter (R241, R282, R284, C267).

Q219 and Q220 change loop filter characteristics to obtain a rapid lockup speed when changing frequencies. These transistors obtain stable oscillation when an oscillating frequency does not change.

### 4-3-4 VCO CIRCUIT (VCO UNIT)

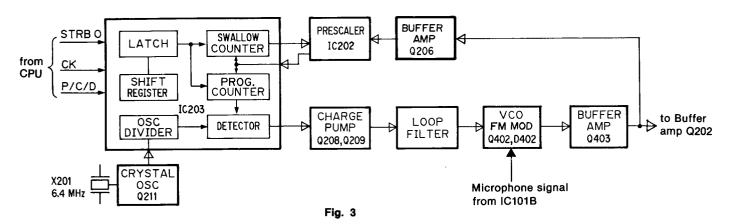
The VCO (Variable Control Oscillator) circuit oscillates the 1st LO frequency in receiving and transmit frequency in transmitting.

The VCO free run frequency is shifted by Q401 using an induction reactance of D402. The generated frequency is controlled by D401 using the lock voltage output from the loop filter.

### 4-4 VOLTAGE LINES

LINE	DESCRIPTION
Vcc	The connected battery pack voltage or the external power supply voltage passed through the power switching relay (RL101) and power switch.
+5 V	Common 5 V regulated from Vcc at Q116, Q117, D117 and D107.
5 V	Common 5 V regulated from Vcc at Q114, Q115 and D106. 5 V is separated from the +5 V line to obtain the desired current capacity.
R5	Receive 5 V regulated from Vcc at Q110, Q111 and D104. A reference voltage uses the "+5 V" switched by Q108 and Q109 using the "T/R" line from the CPU.
Т5	Transmit 5 V regulated from Vcc at Q112, Q113 and D105. A reference voltage uses the "+5 V" switched by Q108 and Q109 using the "T/R" line from the CPU.

### PLL CIRCUIT BLOCK DIAGRAM



### 4-5 LOGIC CIRCUITS

The logic circuit consists of an 8-bit CMOS CPU, 32k-word ROM, 2k-word RAM, 5-Tone encoder, 5-Tone decoder and subaudible tone encoder. The circuit controls frequency and tone setting and the function display, etc.

### 4-5-1 CPU (LOGIC UNIT)

CPU IC701 is  $\mu PD78C06AG$ . The following are the port allocations of each pin.

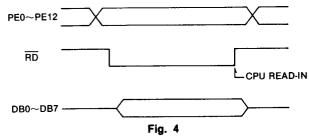
### • CPU PORT ALLOCATIONS

PORT NUMBER	PIN NUMBER	DESCRIPTION	PORT NUMBER	PIN NUMBER	DESCRIPTION
DB0~DB7	5~2 64~61	These are 8-bit data busses for an external ROM and RAM. DB0~DB3 are also used as matrix input ports.	PC3 [FUNC]	13	This is an input port for the [FUNC] switch. The transceiver enters the cloning receive mode when the port is "LOW" at turning the power ON.
PE0∼PE15	43~57 59	These are 16-bit data busses. PE0∼PE7 are used as matrix output ports. PE13∼PE15 are used as select signal ports for the ROM and gate array.	PC2 [SEND]	14	This is an input port for the transmit/receive switching signal. The port is also used as the cloning input.
PA7 [CS]	34	This port becomes "LOW" when IC701 outputs command or data signals to IC601.	PC1 [SQL]	15	This is an input port for the squelch open/close. It becomes "HIGH" when the squelch opens.
PA6 [P/C/D]	33	This port outputs a selector signal for selecting the signal of PLL N-data and IC601 command/data.	PC0 [UNLK]	16	This is an input port for the PLL unlock signal. It becomes "LOW" when the PLL is unlocked.
PA5 [CK]	32	This port outputs a synchronizing clock signal when the PLL N-data	so	21	This port outputs data for the subaudible tone and IC601.
PA4 [TMUT]	31	is output.  This port outputs a transmit mute signal. It becomes "HIGH" when no RF output power is required.	SCK	19	This port outputs a data timming signal of the SO port. The SO signal changes at the leading edge of the SCK output signal.
PA3 [RMUT]	30	This port outputs a receive mute signal. It becomes "HIGH" when no AF output power is required.	INTO .	7	This is an input port for controlling the 5-Tone decoder IC. The 5-Tone decoder data are input when the port becomes "HIGH."
PA1 [CPO]	28	This port outputs cloning data.	INT1	6	IC701 enters the standby mode
PA0 [STRB0]	27	This port outputs a strobe signal for PLL data.			when the port becomes "HIGH." This port becomes "HIGH" and "LOW" when the power is turned
PB6 [STRB2]	41	This port outputs a strobe signal for the CTCSS data.			OFF and ON respectively.
PB5	40	This port outputs a strobe signal	TO [BEEP]	18	This port outputs signals for the beep sound.
[STRB1] PB4 [T/R]	39	for the 5-Tone encoder.  This port controls the switching of transmit/receive. It becomes	WR	9	This port becomes "LOW" when data are stored in the external RAM IC703.
PB0~PB3 [S0~S3]	35~38	"LOW" when transmitting.  These are used as ports of the 5-Tone input/output data.	RD	10	This port becomes "LOW" when data are recalled from the external ROM or RAM.
PC5 [BUSY]	11	This port is an input port for the BUSY signal from IC601.	φοut	60	Not used.
PC4 [TRF]	12	This is an input port for the transmit indicator. The indicator lights when the port becomes "LOW."			

### 4-5-2 ROM (LOGIC UNIT)

ROM IC chip IC702 is a 32768-word, 8-bit CMOS ROM IC chip. The program in IC702 controls the IC701 CPU. The data reading is indicated by addresses PE0 $\sim$ PE12 of IC701, and done at the leading edge of the  $\overline{\text{RD}}$  port signal.

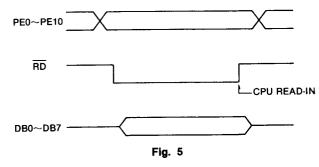
#### **ROM READ TIMING DIAGRAM**



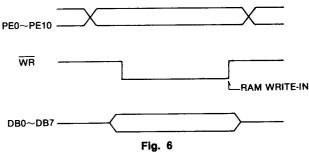
### 4-5-3 RAM (LOGIC UNIT)

RAM IC chip IC703 is a 2048-word, 8-bit CMOS IC chip. IC703 stores data for channels, PLL N-data, tone numbers to the tone frequencies and shift frequencies, etc. Data reading and writing are indicated by addresses PE0 $\sim$ PE10 of IC701, and done by timing signals  $\overline{\text{RD}}$  and  $\overline{\text{WR}}$ .

### RAM READ TIMING DIAGRAM



#### RAM WRITE TIMING DIAGRAM

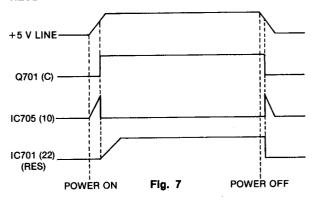


### 4-5-4 RESET CIRCUIT (LOGIC UNIT)

The voltage of the +5 V line rises up to 5 V after the power is turned ON, and the collector of Q701 becomes 5 V. When the collector of Q701 becomes "HIGH," pin 10 of IC705 becomes "LOW" then pin 12 of IC705 changes from "LOW" to "HIGH." The signal is applied to IC601 in the DISPLAY UNIT for resetting. The signal is also applied to IC701 through a delay circuit consisting of C703 and R704. This action delays the CPU resetting slower than the LCD driver resetting.

When the power is turned OFF, pin 10 of IC705 changes from "LOW" to "HIGH." This voltage change is applied to IC701 for entering the CPU standby mode.

#### **RESET TIMING CHART**



# 4-5-5 5-TONE ENCODER/DECODER CIRCUIT (LOGIC UNIT)

IC705 is a gate array IC chip and consists of 5-Tone encoder, 5-Tone decoder data selectors for CPU control, serial/parallel converters, dividers and inverters.

	<del>,</del>	
PORT NUMBER	PIN NUMBER	DESCRIPTION
100~103	64~61	These are input/output ports for the 5-Tone encoder/ decoder data.
CON1	60	This port is used for selecting either the input or output ports of IO0~IO3. It becomes "LOW" for input ports and "HIGH" for output ports.
RX	59	This port is used for selecting either the encoder or decoder function. It becomes "LOW" for encoding and "HIGH" for decoding.
TO1, TO2	44, 45	These ports select one of the 5-Tone sequential systems: CCIR, ZVEI, EEA or EIA.
ST1	57	This port inputs a strobe signal for the 5-Tone encoder/decoder.
EC, EC0~EC2	40~43	These ports output the 5-Tone encoder data.
DS	21	This port is used as an input port for 5-Tone signals.
ST3	8	This port outputs a strobe signal for the 5-Tone decoder data.
SE1~SE3	2~4	This port is used as a data selector input.
MA0~MA3 DB0~DB3 CE1	39~36 55~52 51	Function of each port CE1 and DB0~DB3 is determined by data from ports SE1~SE3. Ports MA0~MA3 are allocated as data input.
ST2, SCK2, SI2	56, 7, 6	These are serial input ports for converting data from serial to parallel.

PORT NUMBER	PIN NUMBER	DESCRIPTION
P1~P7	13~19	These are used as parallel output ports after data are converted from serial to parallel.
IN1, IN2	9, 11	These ports are connected to internal inverter inputs.
OUT1, OUT2	10, 12	These ports are connected to internal inverter outputs.
KO1	5	This port outputs 4.48 MHz signals.
коз	22	This port outputs 560 kHz signals.
TEST, T1, SET, RES, CON2, RCE, RT2, RT1, CP1, DATC, KO5, KO4, KO2	23~25 28~33 46~49	These ports are used for checking the IC testing.

# 4-5-6 SELECTING A 5-TONE SEQUENTIAL (LOGIC UNIT)

One of 4 kinds of 5-Tone sequentials can be selected by the following method: (Refer to p. 7-2.)

	TO1	TO2
EIA	L	L
CCIR	Н	L
EEA	L	Н
ZVEI	Н	Н

# 4-5-7 D/A CONVERTER CIRCUIT (LOGIC UNIT)

EC0 $\sim$ EC2 of IC701 outputs 5-Tone signals digitally. R713 $\sim$ R718 convert signal from digital to analog, and then output the signals as 5-Tones to the MAIN UNIT.

# 4-5-8 SUBAUDIBLE TONE ENCODER CIRCUIT (LOGIC UNIT)

The serial/parallel converter section of IC705 converts serial data from the CPU into tone encoder input data.

IC704 is an IC chip for generating subaudible tone frequency signals from 67 Hz $\sim$ 250.3 Hz. The following table shows the relation between input data and the output frequency of IC704.

#### SUBAUDIBLE TONE ENCODER FREQUENCY TABLE

OUTPUT	IC704 INPUT PIN NUMBER					
FREQUENCY [Hz]	8	9	10	11	12	13
67.0	Н	L	L	L	L	L
71.9	L	Н	L	L	L	L
74.4	Н	Н	L	L	L	L
77.0	L	L	Н	L	L	L
79.7	Н	L	Н	L	L	L
82.5	L	Н	Н	L	L	L
85.4	Н	Н	Н	L	L	L
88.5	L	L	L	Н	L	L
91.5	Н	L	L	Н	L	L
94.8	L	Н	L	Н	L	L
97.4	Н	Н	٦	Н	L	L
100.0	L	L	H	Н	L	L
103.5	Н	L	Ι	Н	L	L
107.2	L	Н	Η	Н	L	L
110.9	Н	Н	Н	Н	L	L
114.8	L	L	لــ	L	Н	L
118.8	Н	L	نا	L	Н	L
123.0	L	Н	L.	L	Н	L
127.3	Н	Н	L	L	Н	L
131.8	L	L	Н	L	Н	L
136.5	Н	L	Н	L	Н	L
141.3	L	Н	Н	L	Н	L
146.2	Н	Н_	Н	L_	Н	L
151.4	L	L_	L	Н_	Н	L
156.7	Н	L	L	Н	Н	L
162.2	L	Н	L	Н	Н	L
167.9	Н	н	L	H	Н	L
173.8	L	L_	Н	Н	Н	L
179.9	H_	L	Н	Н	Н	L
186.2	L	н	Н	Н_	H	L
192.8	Н	Н	Н	Н	Н	L
203.5	L	L	L	L	L	Н
210.7	Н	L	L	L	L	Н
218.1	L	н	L	L	L	Н
225.7	Н	Н	L	L	L	Н
233.6	L_	L_	Н	L	L	Н
241.8	Н	L	Н	L	L	Н
250.3	L	Н	Н	L	LL	Н

H: HIGH L: LOW

# 4-6 DISPLAY CIRCUIT (DISPLAY UNIT)

IC601 is a programmable LCD controller/driver IC chip. Data from the LOGIC UNIT are applied to IC601 and divided by 3 to be indicated on the function display.

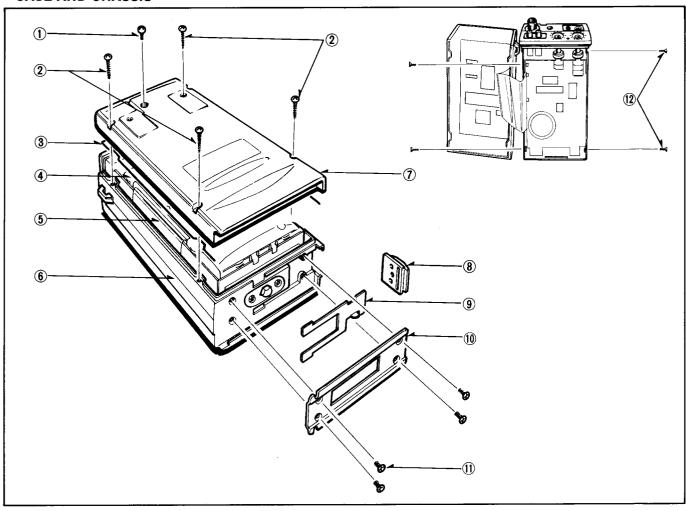
# SECTION 5 MECHANICAL PARTS AND DISASSEMBLY

LABEL NUMBER	DESCRIPTION	ORDERING NUMBER	QTY.	LABEL Number	DESCRIPTION	ORDERING NUMBER	QTY.
1	PH M2×4 ZK*	8810000100	1	<b>3</b> 1)	297 mic lug	8930007210	1
2	PH A0 2×15 ZK*	8810000740	4	32	No. 0-1 PH B0 2×5 ZU*	8810004040	3
3	Casing seal-1	8930002950	1	<b>33</b>	Speaker plate (A)	8930007200	1
4	660 rear shielding plate	8510005490	1	34)	Speaker seal	8930002930	1
(5)	Shielding sheet	8310000010	1	35	No. 0-3 PH B0 1.4×4*	8810001720	4
6	Front panel-1	8210001610	1	36	No. 0-3 PH B0 1.4 × 3.5 ZK*	8810001710	7
1	Rear panel-3	8010004731	1	37)	461 aluminum sheet	8930008460	1
8	Release button	8930005780	1	38	LCD contact strip SRCN-411	8930007790	1
9	Battery pack latch-3	8930005612	1	39	Keyboard-1	8010006041	1
10	Sliding guide (A)	8010002880	1	40	298 aluminum sheet	8930007270	1_
<b>U</b>	FH M2.6×6 Ni*	8810002380	4	41)	Front shielding plate	8510003310	1
12	No. 0-3 FH M2×3*	8810005490	4	42	Ground plate	8930011150	1_
13	Knobs (Squelch, Volume) N-76	8610000570	2	43	LCD reflector	6910001200	1
14	[LIGHT] button K-30R	8610000130	1	44)	LCD shielding plate	8510003320	1
15	[HIGH/LOW] button K-30G	8610000120	1	45	Push spring (I)	8930002500	1
16	Water-resistant cover	8930006050	1	46	PTT plate	8930001090	1
17	Chassis (B)	8010007390	1	47	No. 0-1 PH B0 2×5 ZK*	8810000530	2
	Knob grip for N-76			48	PTT seal	8930006040	1
18	(included with (3) above)			49	Shielding sheet (E)	8930005440	1
19	PH M2×4 ZK*	8810000100	1	50	Screw lug M2.6	8860000020	2
20	Top panel-1	8210001040	1	<b>5</b> 1)	E-ring M2	8860000300	1
<b>(1)</b>	Top ring	8930002940	1	52	Gasket (E)	8930002780	1
22	PA heatsink	8410000140	1	53	Contact holder	8010002740	1
23	PA shielding plate	8510002770	1	54	PH M2.6×6 Ni*	8810001840	2
23	Water-resistant cover for knob	8310005130	2	55	Gasket (F)	8930002790	1
25	PH M2.6×6 Ni*	8810001840	2	56	Spring (A)-1	8930007220	1
26	ANT shielding plate	8510003280	1	<b>§</b> 7	Contact	6510000630	1
27	Chassis (A)	8010007380	1				
28	No. 0-1 PH B0 2×4*	8810004800	3				
29	Ground plate	8930011160	1				
30	Microphone holder	8930001630	1				

\*Screw type Screw: M2×4, etc. Self-tapping screw: A0 2×15, etc. Precision type screw: No. 0-1, etc.

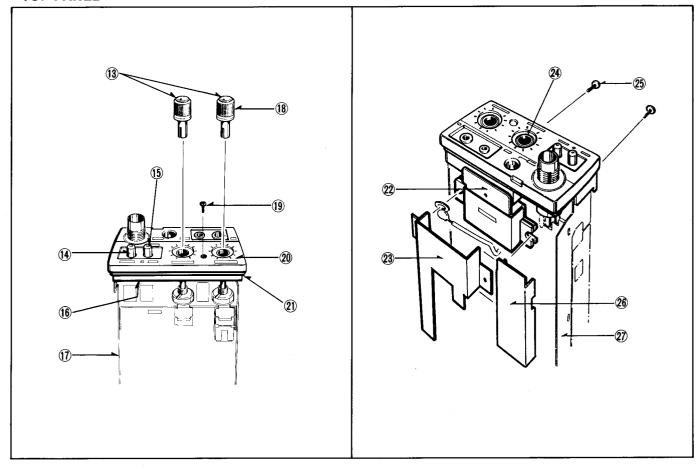
Screw head style PH: Pan head FH: Flat head

### • CASE AND CHASSIS



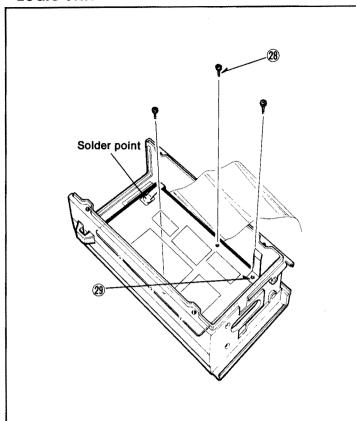
### • TOP PANEL

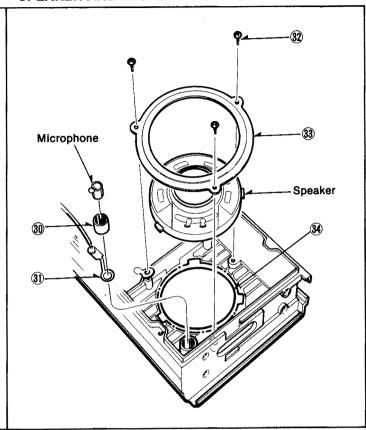
### • PA AND SHIELD CASES



### • LOGIC UNIT

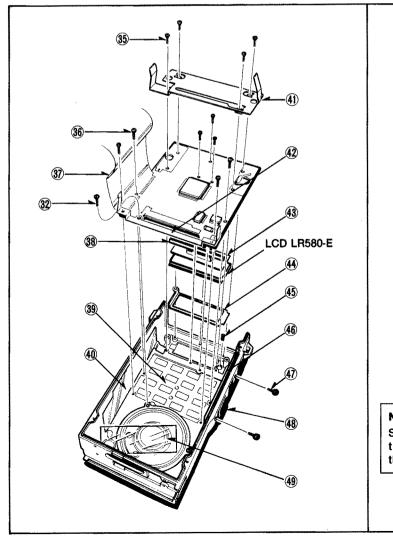
### • SPEAKER AND MICROPHONE

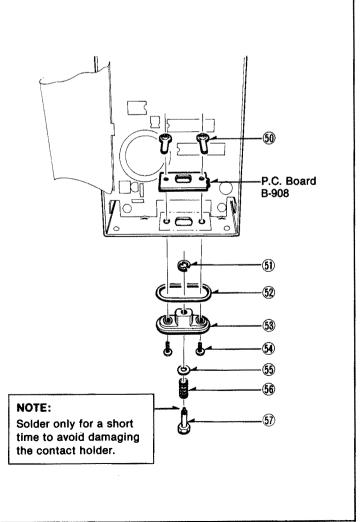




### • DISPLAY AND LCD

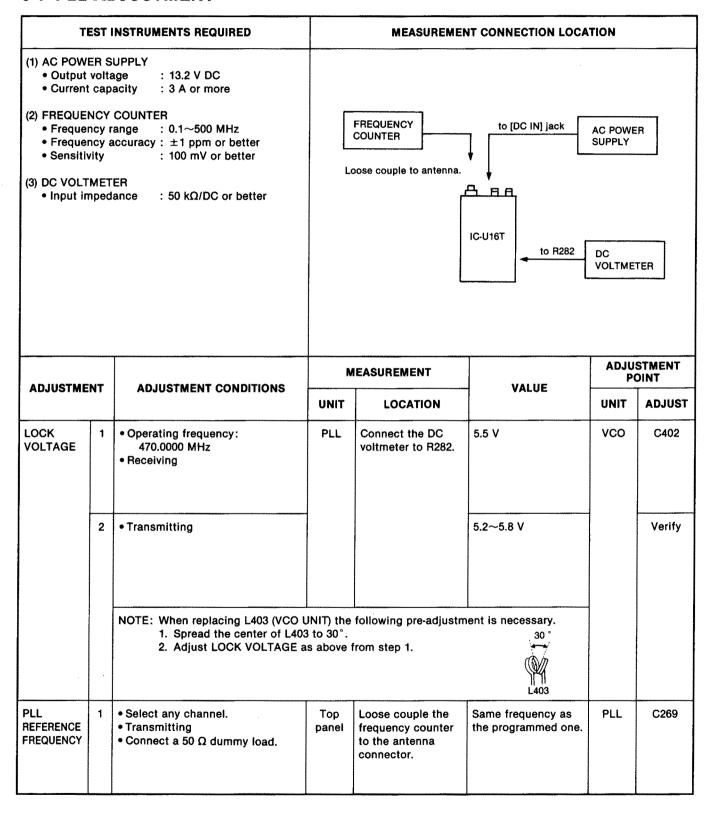
### • CONTACT TERMINAL



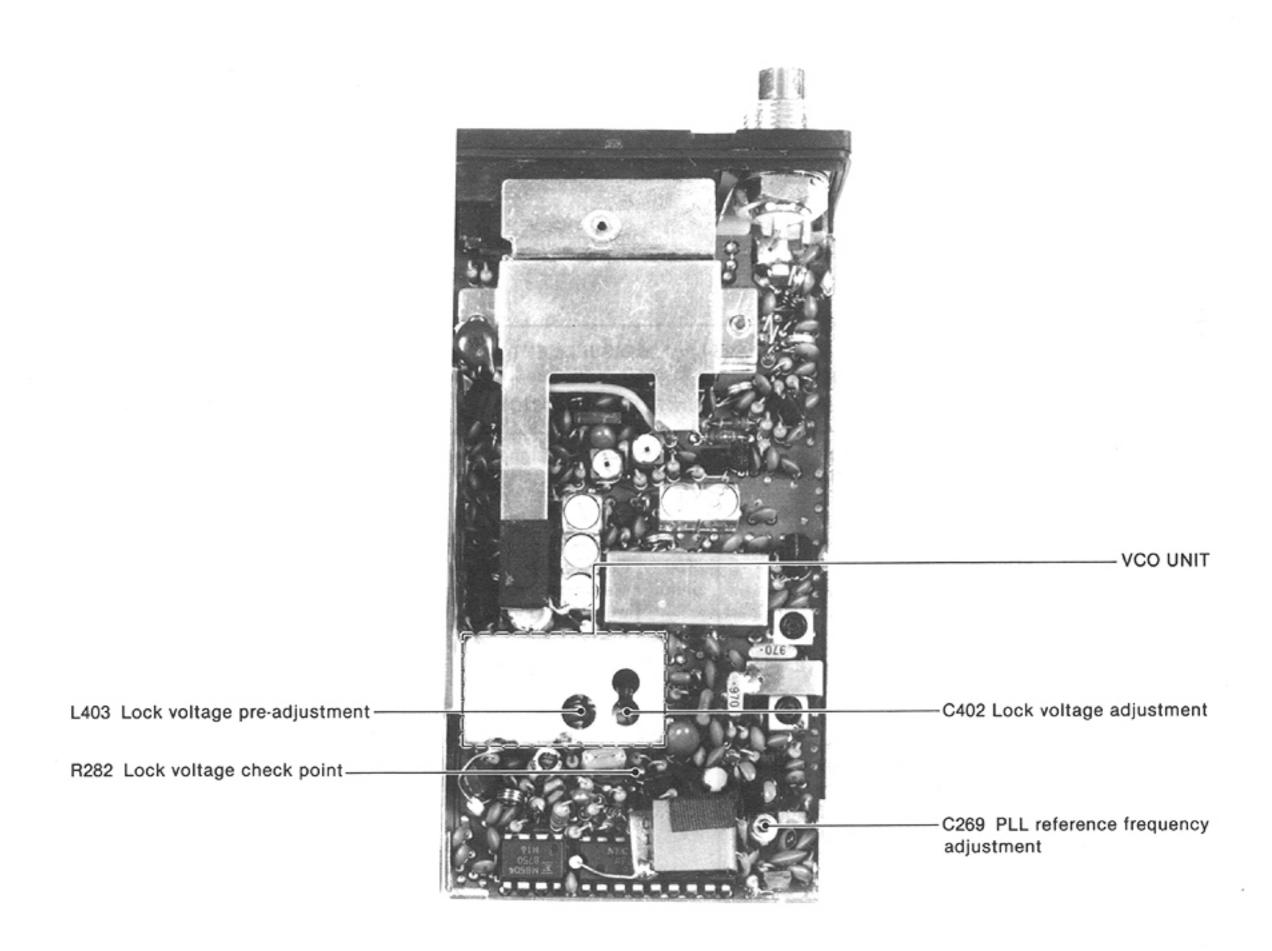


## SECTION 6 ADJUSTMENT PROCEDURES

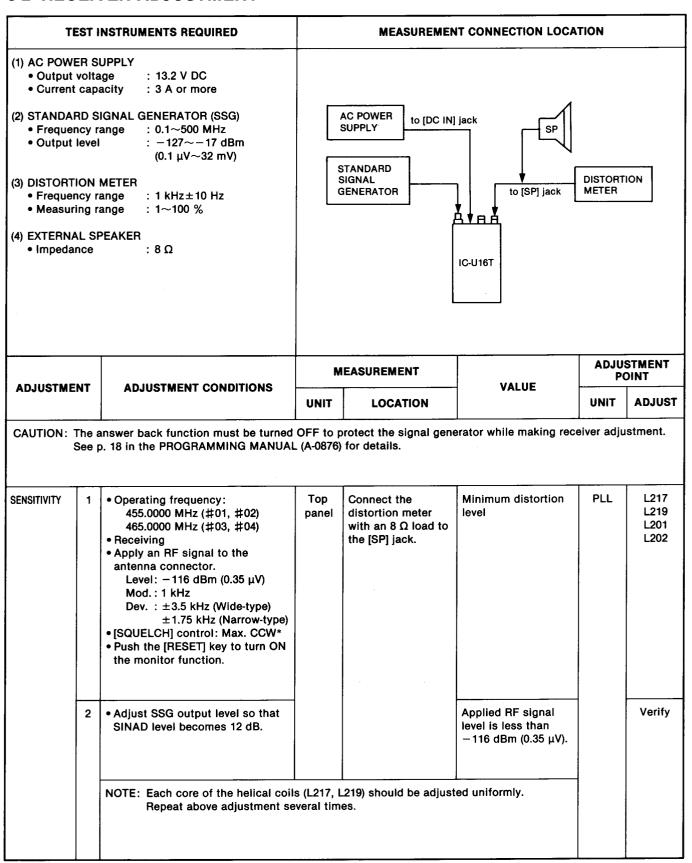
### **6-1 PLL ADJUSTMENT**



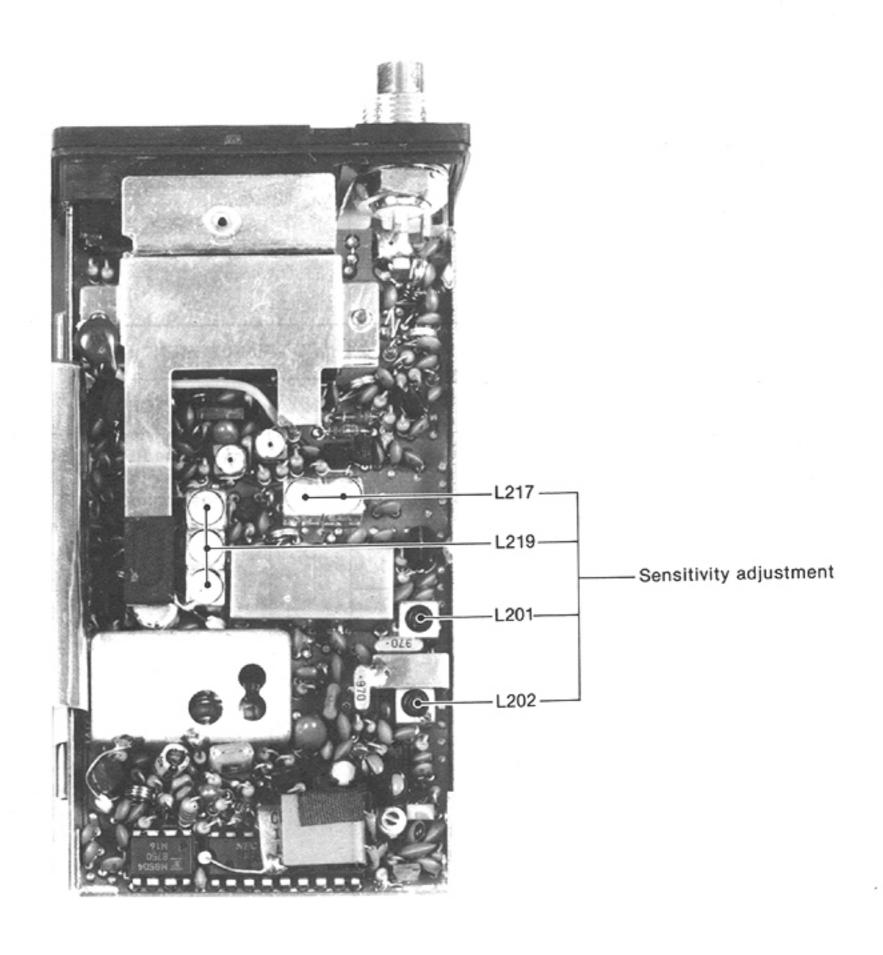
# **PLL AND VCO UNITS**



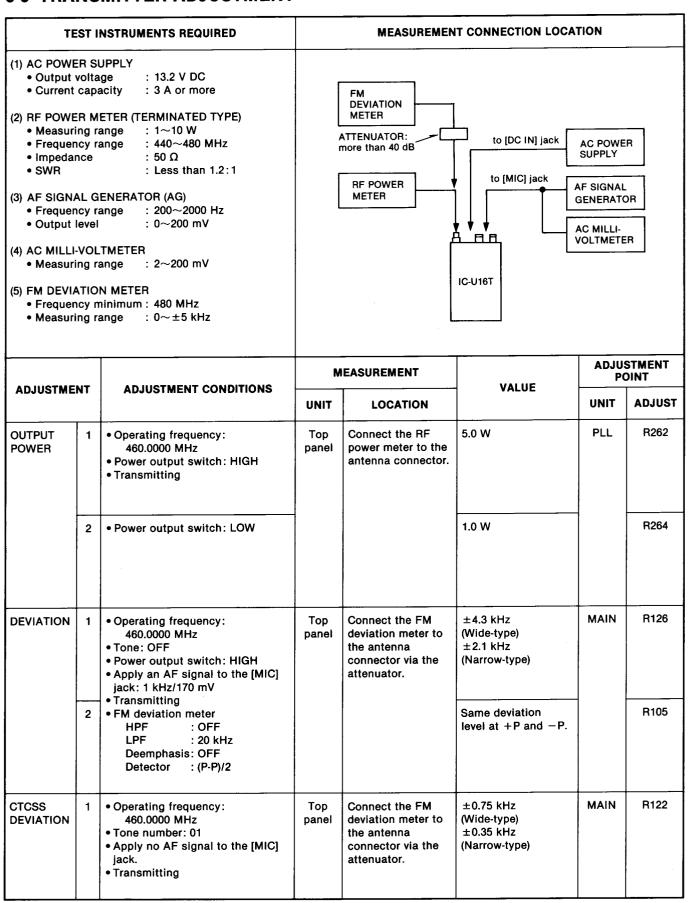
### **6-2 RECEIVER ADJUSTMENT**



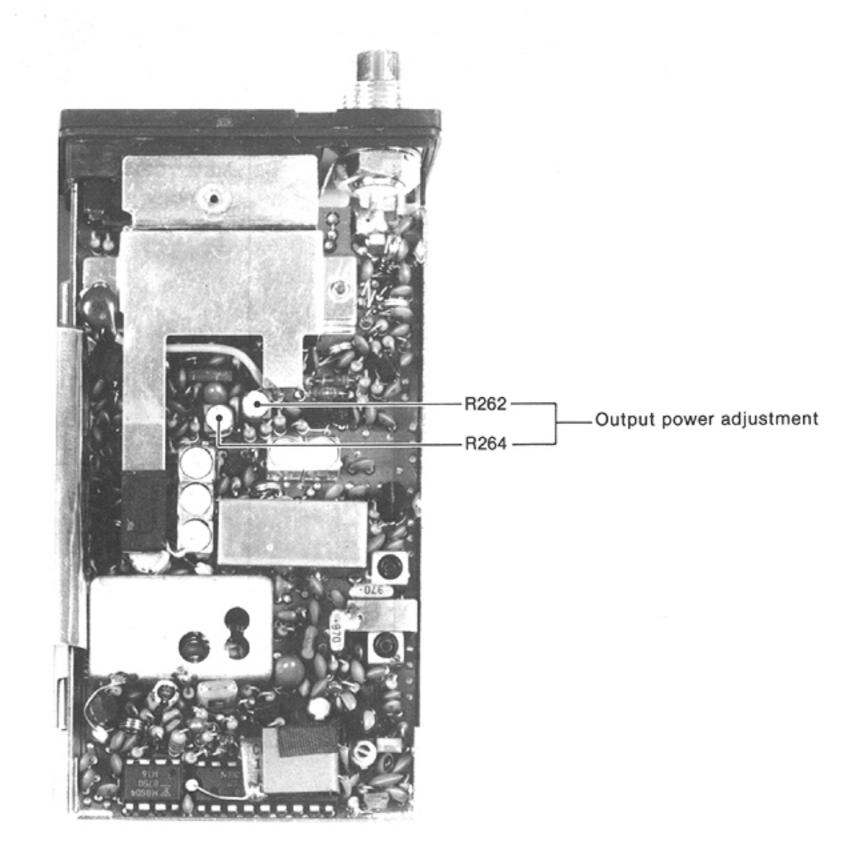
<sup>\*</sup>CCW: Counterclockwise.



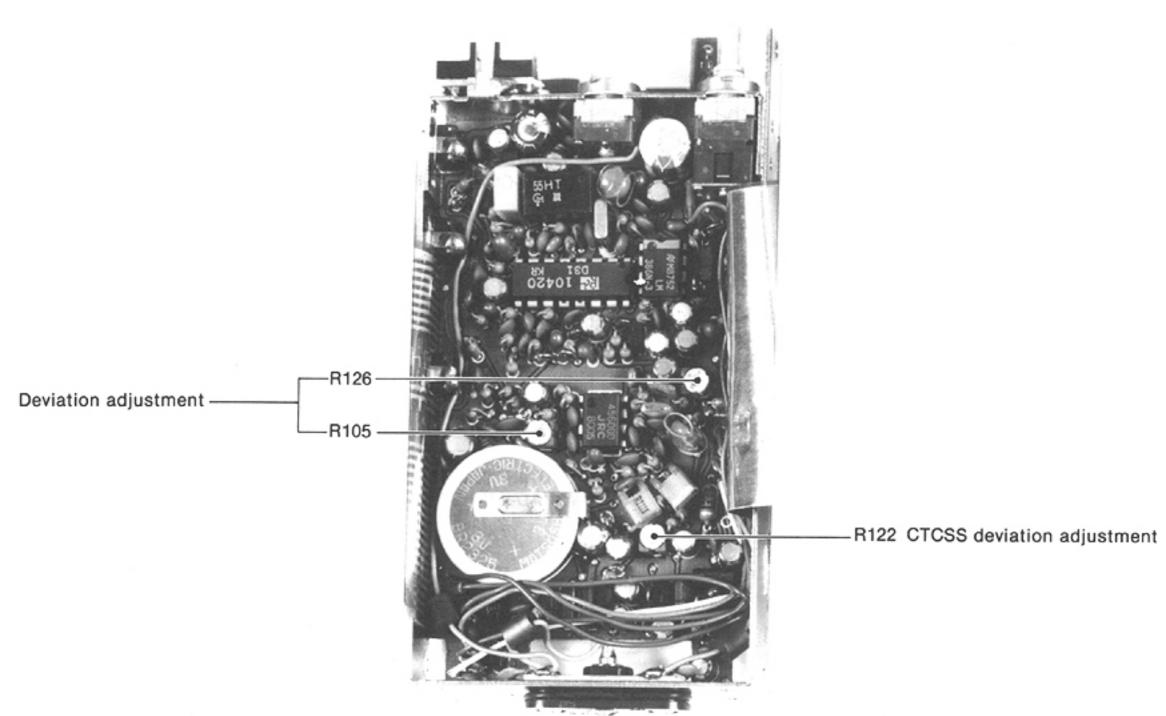
### 6-3 TRANSMITTER ADJUSTMENT



# **PLL UNIT**

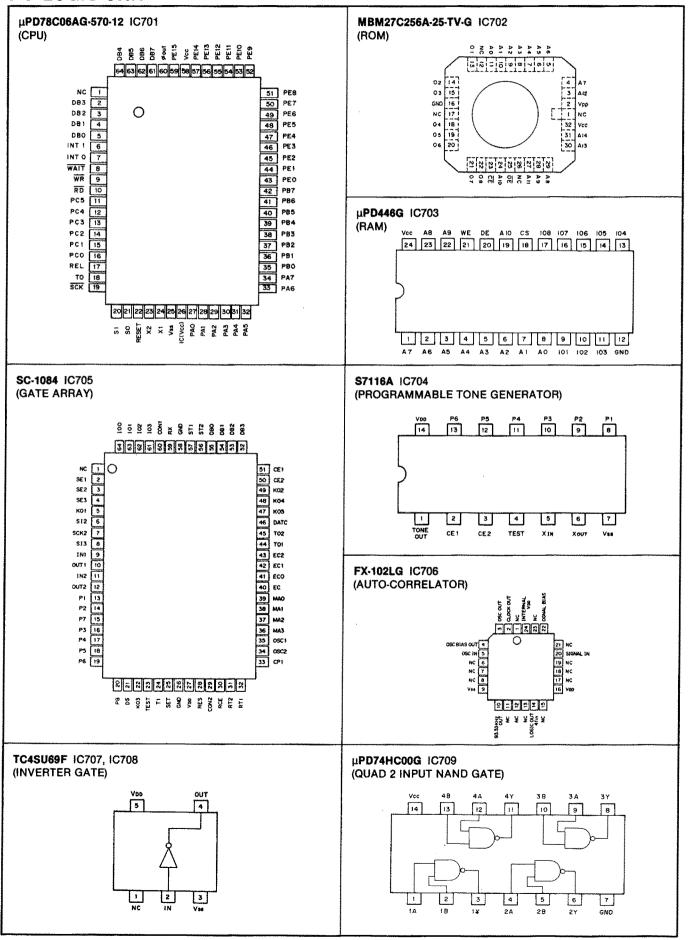


# **MAIN UNIT**

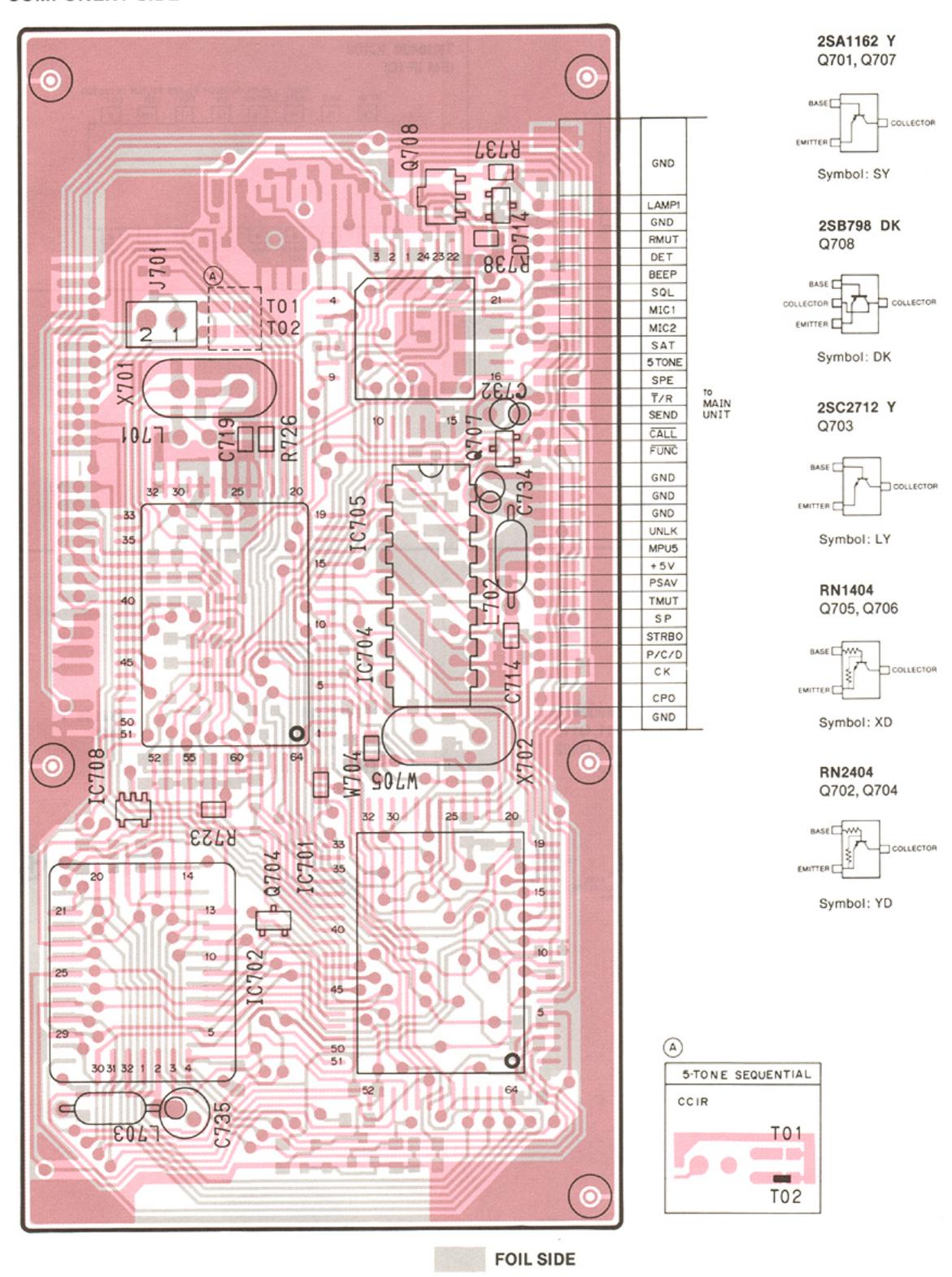


### SECTION 7 BOARD LAYOUTS

### 7-1 LOGIC UNIT

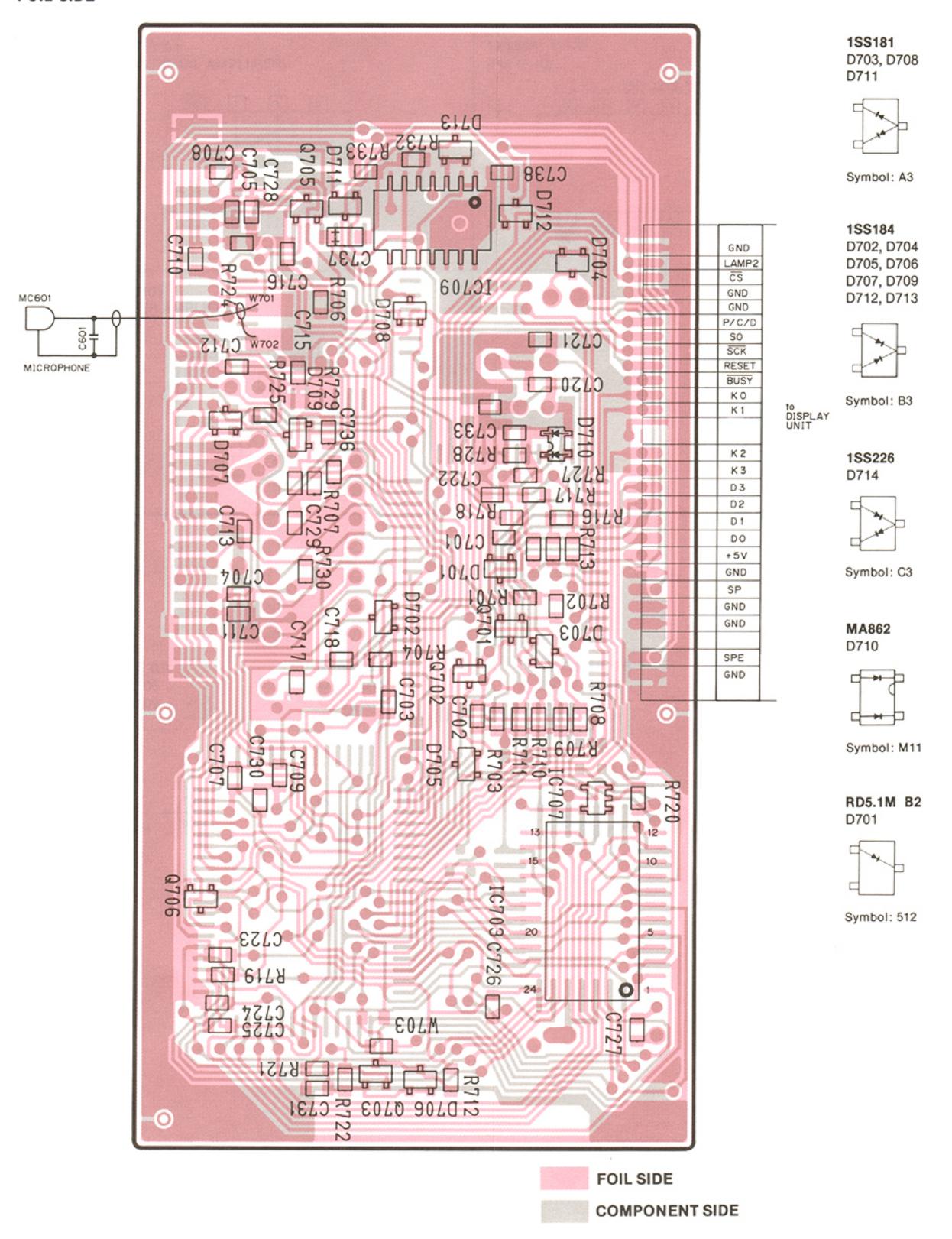


# **COMPONENT SIDE**

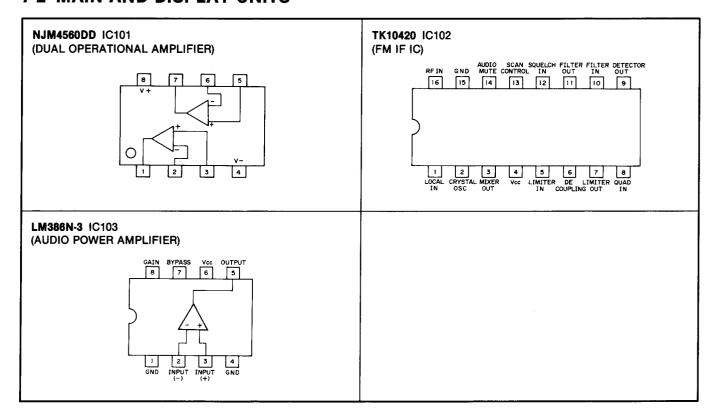


COMPONENT SIDE

# **FOIL SIDE**



### 7-2 MAIN AND DISPLAY UNITS



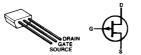
2SA1048 GR Q105, Q106 Q108, Q109 2SB909M R Q111, Q115 Q117, Q122 Q113

2SC2458 GR Q107, Q110 Q112, Q114 Q116, Q118 Q121, Q123 Q124, Q125 **2SJ105 Y** Q120

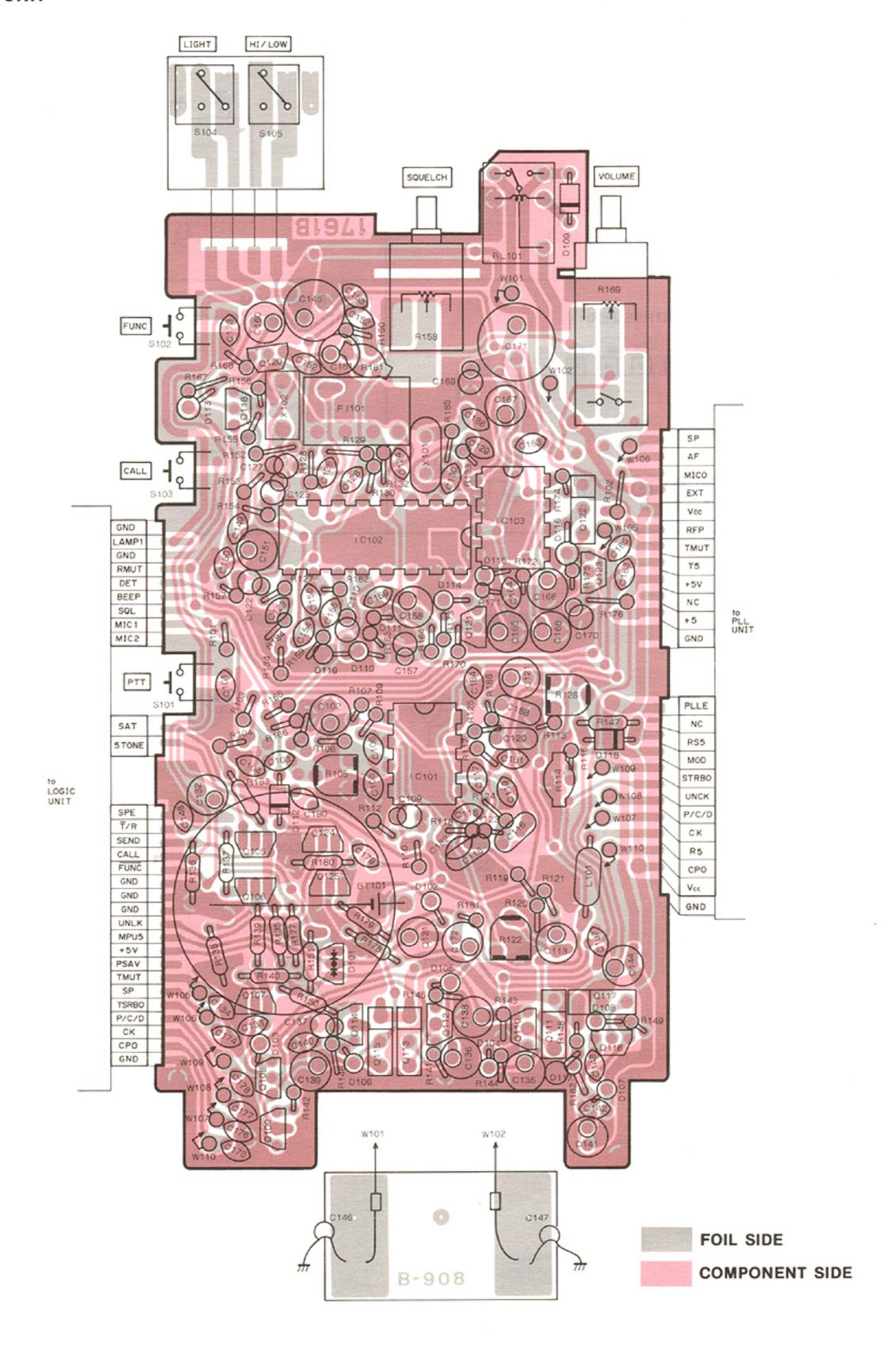




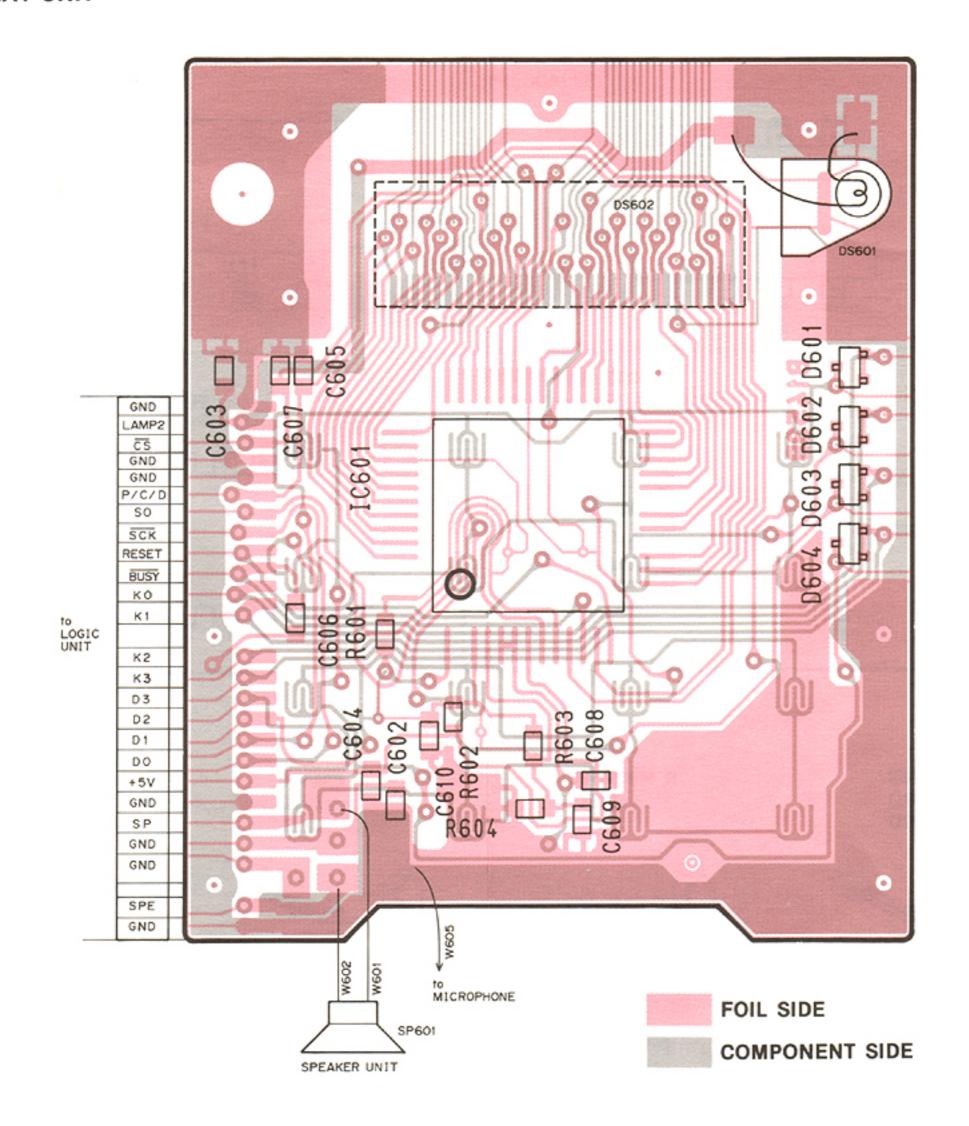


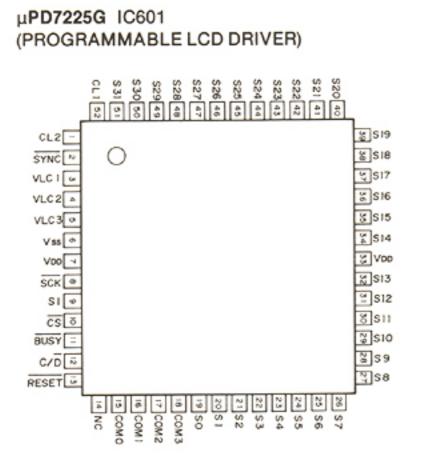


# MAIN UNIT



# DISPLAY UNIT



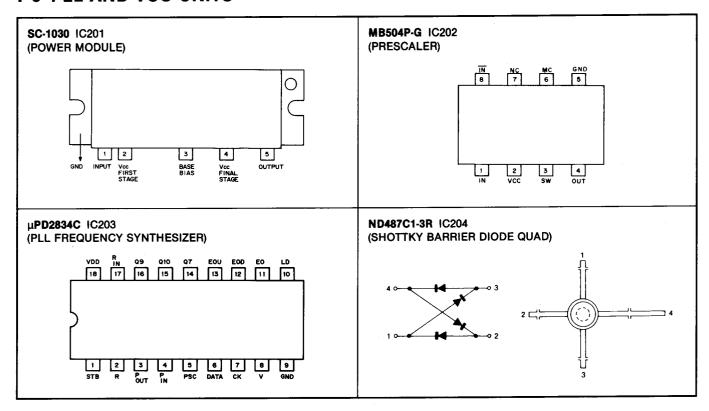


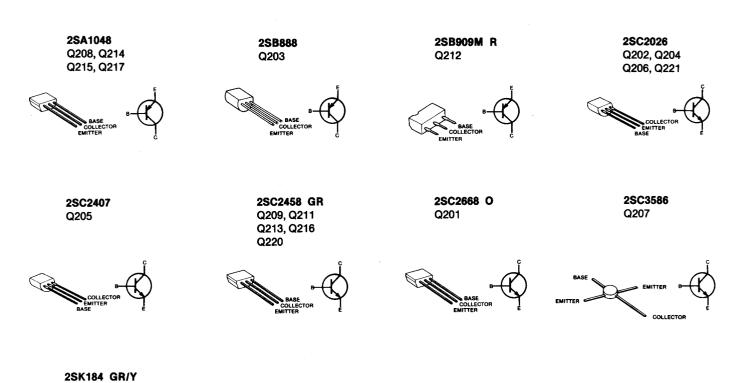
1SS193 D601, D602 D603, D604



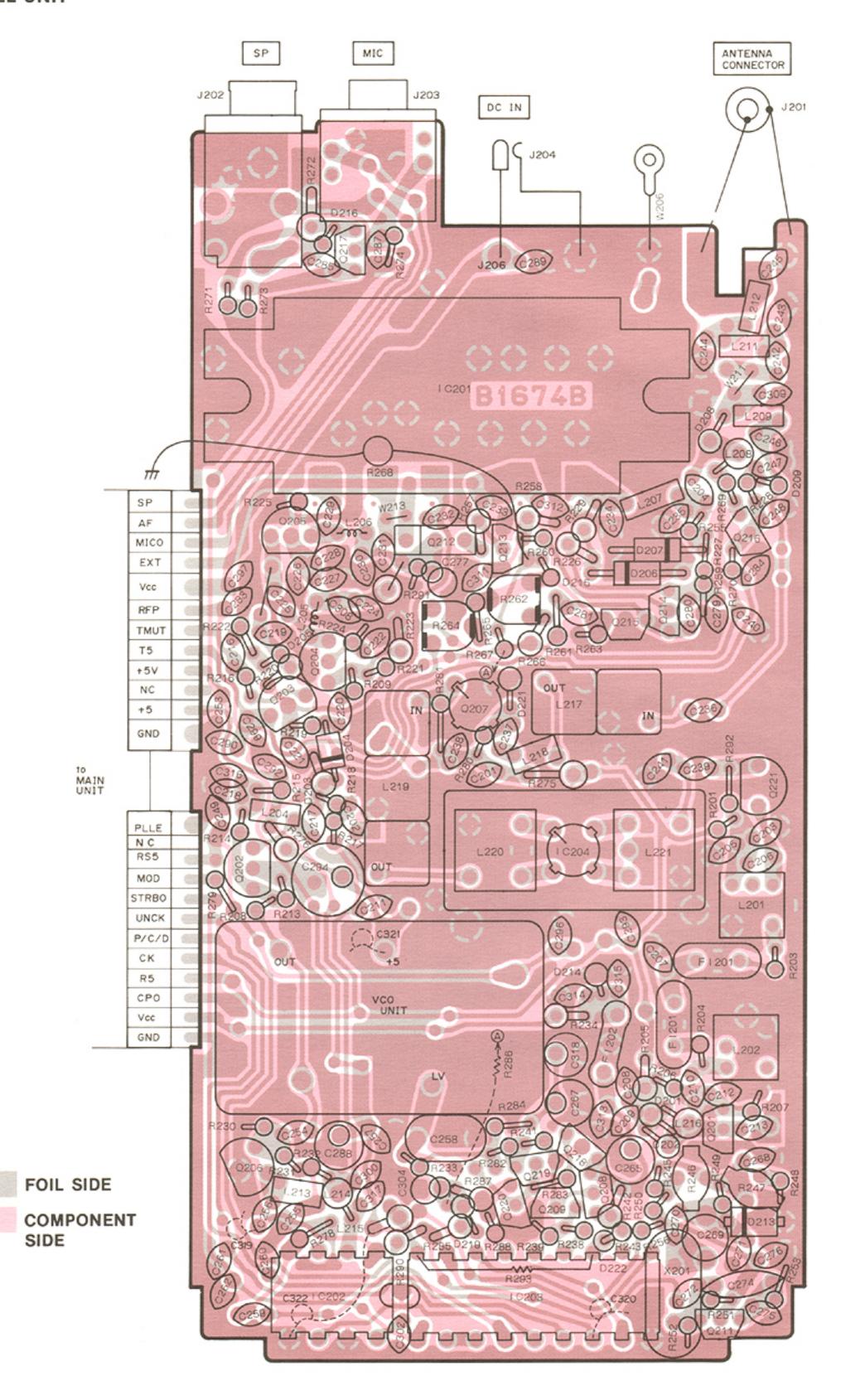
Symbol: F3

### 7-3 PLL AND VCO UNITS

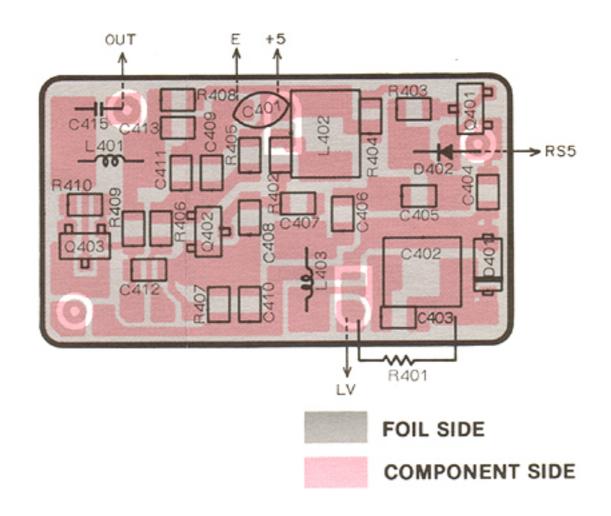


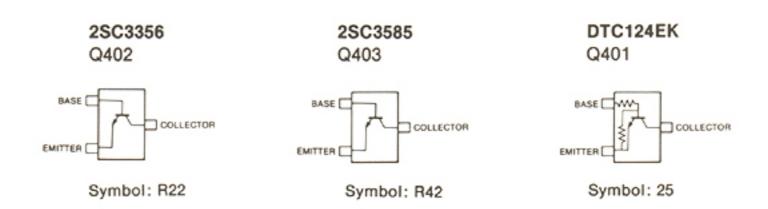


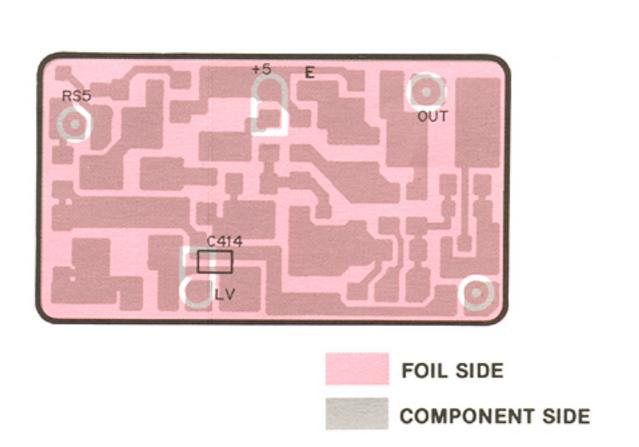
Q218, Q219



# VCO UNIT







### [LOGIC UNIT]

LOGIC	ONII	
REF. NO.	DESCRIPTION	PART NO.
IC701	IC	μPD78C06AG-570-12
IC702	IC	MBM27C256A-25-TV-G
		(SC-1098A: data programmed)
IC703	IC.	μPD446G
IC704 IC705	I IC	S7116A SC-1084
IC706	lic	FX-102LG
IC707	ic	TC4SU69F
IC708	IC	TC4SU69F
IC709	IC	μPD74HC00G
Q701	Transistor	2SA1162 Y
Q702	Transistor	RN2404
Q703	Transistor	2SC2712 Y
Q704	Transistor	RN2404
Q705 Q706	Transistor Transistor	RN1404 RN1404
Q707	Transistor	2SA1162 Y
Q708	Transistor	2SB798 DK
D701	Zener	RD5.1M B2
D702	Diode	1SS184
D703	Diode	1SS181
D704	Diode	1SS184
D705	Diode	1SS184
D706	Diode	1SS184
D707	Diode	1SS184
D708 D709	Diode   Diode	1SS181 1SS184
D710	Diode	MA862
D711	Diode	1SS181
D712	Diode	1SS184
D713	Diode	1SS184
D714	Diode	1SS226
X701	Crystal	FAGNKD (4.48 MHz)
X702	Crystal	FAANKD (3.58 MHz)
L701	Coll	LAL03NA 331K 330µ
L702	Coil	LAL03NA 221K 220µ
L703	Coil	LAL03NA 221K 220μ
R701	Resistor	27 kΩ MCR10
R702 R703	Resistor Resistor	22 kΩ MCR10 22 kΩ MCR10
R703	Resistor	22 kΩ MCR10 270 kΩ MCR10
R706	Resistor	2.2 MΩ MCR10
R707	Resistor	47 kΩ MCR10
R708	Resistor	12 kΩ MCR10
R709	Resistor	12 kΩ MCR10
R710	Resistor	12 kΩ MCR10
R711 R712	Resistor Resistor	12 kΩ MCR10 47 kΩ MCR10
R712 R713	Resistor	100 kΩ MCR10
R714	Resistor	100 kΩ MCR10
R715	Resistor	100 kΩ MCR10
R716	Resistor	47 kΩ MCR10
R717	Resistor	47 kΩ MCR10
R718	Resistor	47 kΩ MCR10
R719	Resistor	47 kΩ MCR10
R720 R721	Resistor Resistor	47 kΩ MCR10 10 kΩ MCR10
R722	Resistor	4.7 kΩ MCR10
R723	Resistor	47 kΩ MCR10
R724	Resistor	15 kΩ MCR10

### [LOGIC UNIT]

	I		
REF. NO.	DESCRIPTION	PART	r NO.
R725	Resistor	4.7 kΩ	MCR10
R726	Resistor	2.7 kΩ	MCR10
R727	Resistor	10 kΩ	MCR10
R728 R729	Resistor Resistor	10 kΩ 47 kΩ	MCR10 MCR10
R730	Resistor	220 kΩ	MCR10
R731	Resistor	47 kΩ	MCR10
R732	Resistor	10 kΩ	MCR10
R733	Resistor	1 ΜΩ	MCR10
R737	Resistor	12 Ω	MCR10
R738	Resistor	5.6 kΩ	MCR10
C701	Ceramic	0.01 μF	GRM40 F
C702	Ceramic	0.01 μF	GRM40 F
C703 C704	Ceramic Ceramic	0.1 μF 470 pF	GRM40 F GRM40
C705	Ceramic	470 pF	GRM40
C707	Ceramic	470 pF	GRM40
C708	Ceramic	470 pF	GRM40
C709	Ceramic	470 pF	GRM40
C710 C711	Ceramic	470 pF 470 pF	GRM40 GRM40
C711	Ceramic Ceramic	470 pF	GRM40
C712	Ceramic	470 pF	GRM40
C714	Ceramic	0.01 μF	GRM40 F
C715	Ceramic	0.01 μF	GRM40 F
C716	Ceramic	0.0022 μF	
C717	Ceramic	18 pF	GRM40
C718 C719	Ceramic Ceramic	18 pF 470 pF	GRM40 GRM40
C720	Ceramic	47 pF	GRM40
C721	Ceramic	18 pF	GRM40
C722	Ceramic	0.01 µF	GRM40 F
C723	Ceramic	470 pF	GRM40
C724	Ceramic	470 pF	GRM40
C725 C726	Ceramic Ceramic	0.01 μF 0.01 μF	GRM40 F GRM40 F
C727	Ceramic	0.01 μF	GRM40 F
C728	Ceramic	0.01 μF	GRM40 F
C729	Ceramic	0.01 μF	GRM40 F
C730	Ceramic	470 pF	GRM40
C731 C732	Ceramic Tantalum	47 pF 4.7 μF	GRM40 16 V DN
C732	Ceramic	0.01 μF	GRM40 F
C734	Tantalum	22 μF	16 V DN
C735	Electrolytic		6.3 V RC3
C736	Ceramic	•	GRM40 F
C737 C738	Tantalum Ceramic	1 μF	16 V SV GRM40 F
0130	Geranno	υ.υ ι μ <b>Γ</b>	GINTO F
J701	Connector	IMSA-9201	B-2-02T
P701	Connector	IMSA-9201	в-нт
SO701	Socket	IC61-0324-	017
W701 W702	Shield Cable	1	W16A/W16A
W702 W703	Jumper	MCR10-JP	w A A)
W704	Jumper	MCR10-JP	
W705	Jumper	MCR10-JP	
EP701	P.C. Board	B-1867A	

# [DISPLAY UNIT]

REF. NO.	DESCRIPTION	PART	NO.
IC601	IC	μPD72250	ì
D601	Diode	1SS193	
D602	Diode	188193	
D603	Diode	188193	
D604	Diode	188193	
R601	Resistor	180 kΩ	MCR10
R602	Resistor	10 kΩ	MCR10
R603	Resistor	10 kΩ	MCR10
R604	Resistor	10 kΩ	MCR10
C601	Ceramic	470 pF	50 V
C603	Ceramic	470 pF	GRM40
C604	Ceramic	0.001 uF	GRM40
C605	Ceramic	470 pF 470 pF 0.001 μF 47 pF 47 pF 47 pF 0.001 μF	GRM40
C606	Ceramic	47 pF	GRM40
C607	Ceramic	47 pF	GRM40
C608	Ceramic	0.001 μF	GRM40
C609	Ceramic	0.001 μF 0.001 μF	GRM40
C610	Ceramic	0.001 μF	GRM40
DS601	Lamp	BQ031-224	103A
DS602	LCD	LR580-E	
MC601	Microphone	KUC2023-0	01-006
SP601	Speaker	40P-157B	
W601	Wire	23/04/050/\	W01/W01
W602	Wire	23/00/040/\	W01/W01
W605	Wire	23/00/040/\	W01/W01
EP601	LCD Contact Strip	SRCN-411	
EP603	P.C. Board	B-1453B	
EP604	F.P.C. Board	B-1046A (I	DISPLAY~LOGIC)

### [MAIN UNIT]

REF. NO.	DESCRIPTION	PART NO.
IC101	IC	NJM4560DD
IC102	IC	TK10420
IC103	IC	LM386N-3
Q105	Transistor	2SA1048 GR
Q106	Transistor	2SA1048 GR
Q107	Transistor	2SC2458 GR
Q108	Transistor	2SA1048 GR
Q109	Transistor	2SA1048 GR
Q110	Transistor	2SC2458 GR
Q111	Transistor	2SB909M R
Q112	Transistor	2SC2458 GR
Q113	Transistor	2SB909M R
Q114	Transistor	2SC2458 GR
Q115	Transistor	2SB909M R
Q116	Transistor	2SC2458 GR
Q117	Transistor	2SB909M R
Q118	Transistor	2SC2458 GR
Q120	FET	2SJ105 Y

### [MAIN UNIT]

	<u> </u>		
REF. NO.	DESCRIPTION	PAR	Г NO.
Q121	Transistor	2SC2458	GR
Q122	Transistor	2SB909M	
Q123	Transistor	2SC2458	
Q124	Transistor	2SC2458	
Q125	Transistor	2SC2458	GR
D101	Diode	1SS233	
D101 D102	Diode	1SS254	
D102	Diode	155254	
D104	Diode	<b>1SS254</b>	
D105	Diode	1\$\$254	
D106	Diode	1SS254	
D107	Zener	RD5.1JS	B2
D108	Diode Diode	1SS254 1SS254	
D109 D110	Diode	18953	
D111	Diode	188254	
D112	Diode	1SS254	
D113	Diode	1SS254	
D114	Diode	1SS254	
D115	Diode	1SS254	•
D116	Zener Zener	RD4.7E B RD6.8E B	
D117 D118	Diode	1SS254	· <b>Z</b>
D119	Diode	18953	
21.0	2.000		
FI101	Ceramic	CFW455H	T (Narrow)
		CFW455E	(Wide)
		05.044	
X101 X102	Crystal Discriminator	CR-214 CDB455 (	274
X102	Discriminator	CDB455 C	<i>71</i> A
L101	Coil	LAL03NA	100K 10µ
R101	Resistor	33 kΩ	ELR20
R102	Resistor	1 kΩ	ELR20
R103	Resistor	1 kΩ	ELR20
R104	Resistor	1.2 kΩ	ELR20
R105	Trimmer		RH0421CS5J02A
R106 R107	Resistor Resistor	220 kΩ 470 Ω	ELR20 ELR20
R107	Resistor	180 kΩ	ELR20
R110	Resistor	10 kΩ	ELR20
R112	Resistor	120 Ω	ELR20
R113	Resistor	10 kΩ	ELR20
R114	Thermistor	33D28	El Boo
R115 R117	Resistor Resistor	22 kΩ 220 kΩ	ELR20 ELR20
R118	Resistor	68 kΩ	ELR20
R119	Resistor	39 kΩ	ELR20
R120	Resistor	33 kΩ	ELR20
R121	Resistor	10 kΩ	ELR20
R122	Trimmer	100 kΩ	RH0421C15J06A
R123	Resistor	39 kΩ	ELR20
R124	Resistor	56 kΩ 39 kΩ	ELR20 (Narrow) ELR20 (Wide)
R125	Resistor	12 kΩ	ELR20
R126	Trimmer	100 kΩ	RH0421C15J06A
R127	Resistor	470 Ω	ELR20
R128	Resistor	1.5 kΩ	ELR20
R129	Resistor	47 kΩ	ELR20
R130	Resistor	2.2 kΩ 1.5 kΩ	ELR20 (Narrow) ELR20 (Wide)
R132	Resistor	2.2 kΩ	ELR20 (Narrow)
		1.5 kΩ	ELR20 (Wide)
R133	Resistor	4.7 kΩ	ELR20
R134	Resistor	68 kΩ	ELR20 (Narrow)
R135	Resistor	180 kΩ 560 Ω	ELR20 (Wide) R20
R136	Resistor	10 kΩ	R20

### [MAIN UNIT]

### [MAIN UNIT]

REF. NO.	DESCRIPTION	PART	NO.
R137	Resistor	100 kΩ	R20
R138	Resistor	100 kΩ	R20
R139	Resistor	220 kΩ	R20
R140	Resistor Resistor	33 kΩ 10 kΩ	R20 ELR20
R141 R142	Resistor	180 kΩ	ELR20
R143	Resistor	10 kΩ	ELR20
R144	Resistor	10 kΩ	ELR20
R145	Resistor	10 kΩ	ELR20
R146	Resistor	10 kΩ	ELR20
R147 R148	Resistor Resistor	18 kΩ 2.7 kΩ	R20 ELR20
R149	Resistor	2.7 kΩ 10 kΩ	ELR20
R150	Resistor	10 kΩ	R20
R151	Resistor	100 kΩ	R20
R152	Resistor		ELR20
R153	Resistor	1 ΜΩ	ELR20
R154 R155	Resistor Resistor	470 kΩ 4.7 kΩ	ELR20 ELR20
R156	Resistor	820 Ω	ELR20
R157	Resistor	12 kΩ	ELR20
R158	Variable Resistor		RK094111000NA
R159	Resistor	2.7 kΩ	ELR20
R160	Resistor	2.2 kΩ 33D28	ELR20
R161 R162	Thermistor Resistor	33D28 1 MΩ	ELR20
R163	Resistor	100 kΩ	ELR20
R164	Resistor	22 kΩ	ELR20
R165	Resistor	1 kΩ	ELR20
R166	Resistor	10 kΩ	ELR20
R167	Resistor	470 kΩ 1 MΩ	ELR20
R168 R169	Resistor Variable Resistor		ELR20 RK0941111003A
R170	Resistor	220 kΩ	ELR20
R171	Resistor	150 kΩ	ELR20
R172	Resistor	150 kΩ	ELR20
R173	Resistor	33 kΩ	ELR20
R174	Resistor		ELR20 (Narrow) ELR20 (Wide)
R175	Resistor	1.8 kΩ 1.2 kΩ	ELR20 (Wide)
R176	Resistor	47 kΩ	ELR20
R177	Resistor	100 kΩ	R20
R178	Resistor	470 kΩ	R20
R179	Resistor	33 kΩ 39 kΩ	R20
R180 R181	Resistor Resistor	39 kΩ 22 kΩ	R20 ELR20
R182	Resistor	3.3 kΩ	ELR20
R183	Resistor	10 kΩ	R20
R184	Resistor	10 kΩ	ELR20
R185	Resistor	1.5 kΩ	ELR20
R186	Resistor	1 kΩ	ELR20
C101	Ceramic	0.001 μF	50 V
C102	Electrolytic	10 μF	16 V RC3
C103	Barrier Layer	0.01 μF	25 V 50 V
C104 C105	Ceramic Ceramic	0.001 μF 47 pF	50 V
C105	Ceramic	47 pF	50 V
C109	Tantalum	0.1 μF	35 V DN
C110	Tantalum	0.1 μF	35 V DN
C113	Electrolytic	0.22 μF	50 V RC3
C115	Mylar Mylar	0.0022 μF	
C116 C117	Mylar Ceramic	0.01 μF 470 pF	50 V F2D 50 V
C118	Ceramic	120 pF 100 pF	50 V (Narrow) 50 V (Wide)
C119	Ceramic	470 pF	50 V
C120	Mylar	0.0022 μF	50 V F2D
C121	Electrolytic	1 μF	50 V RC3
1	Tantalum	0.1 μF	35 V DN
C122	Coross!-	^ ^^4 ··⊏	
C123	Ceramic Barrier Laver	0.001 μF 0.01 μF	50 V 25 V
	Ceramic Barrier Layer Tantalum	0.001 μF 0.01 μF 10 μF	50 V 25 V 16 V DN

REF. NO.	DESCRIPTION	PART	NO.
C127	Tantalum	0.1 μF	35 V DN
C128	Ceramic	0.1 μF	D33Y5V1E104Z21
C129	Ceramic	56 pF	50 V
C130	Ceramic Electrolytic	18 pF 47 μF	50 V 6.3 V RC3
C131 C132	Electrolytic	47 μF 4.7 μF	50 V RC3
C133	Ceramic	0.001 μF	50 V
C134	Ceramic	470 pF	50 V
C135	Electrolytic	22 μF	6.3 V RC3
C136	Electrolytic Tantalum	22 μF 4.7 μF	6.3 V RC3 16 V DN
C137 C138	Electrolytic	4.7 μF	50 V RC3
C139	Electrolytic	22 μF	6.3 V RC3
C140	Ceramic	0.001 μF	50 V
C141	Electrolytic	22 μF	6.3 V RC3 50 V
C142 C143	Ceramic Ceramic	0.001 μF 470 pF	50 V
C144	Electrolytic	22 μF	6.3 V RC3
C145	Electrolytic	47 μF	25 V MS7
C146	Ceramic	470 pF	50 V
C147 C148	Ceramic Ceramic	470 pF 470 pF	50 V 50 V
C148	Barrier Layer	470 μF	25 V
C150	Ceramic	0.1 μF	D33Y5V1E104Z21
C151	Electrolytic	0.1 μF	50 V RC3
C152	Ceramic	0.0022 μF 0.001 μF	25 V (Narrow) 50 V (Wide)
C153	Ceramic	0.001 μF 47 pF	50 V (VVIde)
C153	Ceramic	0.001 μF	50 V
C155	Ceramic	10 pF	50 V
C156	Ceramic	0.001 μF	50 V
C157	Tantalum Electrolytic	0.47 μF 0.1 μF	35 V DN 50 V RC3
C158 C159	Electrolytic Ceramic	0.1 μF 0.001 μF	50 V RCS
C160	Electrolytic	1 μF	50 V RC3
C161	Electrolytic	1 μF	50 V RC3
C162	Barrier Layer	0.0056 μF	
C163 C164	Ceramic Ceramic	0.1 μF 470 pF	D33Y5V1E104Z21 50 V
C165	Electrolytic	2.2 μF	50 V RC3
C166	Electrolytic	10 μF	16 V RC3
C167	Electrolytic	10 μF	16 V RC3
C168	Electrolytic	10 μF 2.2 μF	16 V RC3 16 V DN
C169 C170	Tantalum Tantalum	2.2 μr 0.68 μF	35 V DN
C171	Electrolytic	220 μF	10 V MS9
C172	Electrolytic	4.7 μF	25 V RC3
C173	Ceramic	470 pF	50 V
C174 C175	Ceramic Ceramic	470 pF 47 pF	50 V 50 V
C176	Ceramic	47 pF	50 V
C177	Ceramic	47 pF	50 V
C178	Ceramic	47 pF	50 V
C179 C180	Ceramic Ceramic	0.1 μF 0.1 μF	D33Y5V1E104Z21 D33Y5V1E104Z21
C181	Ceramic	120 pF	50 V
C182	Ceramic	470 pF	50 V
C183	Ceramic	0.1 μF	D33Y5V1E104Z21
C184 C185	Ceramic Ceramic	0.1 μF 0.001 μF	D33Y5V1E104Z21 50 V
C186	Ceramic	0.001 μF	50 V
C187	Ceramic	0.001 μF	50 V
C188	Mylar	0.0068 μF	
RL101	Relay	OUC-SH-1	14D
0.45	Outlet	OKULTATA	40A IDTT
S101 S102	Switch Switch	SKHHAKO SKHHAKO	13A [PTT] 13A [FUNC]
S102 S103	Switch		13A [CALL]
S104	Switch	SPPH2203	9A [LAMP]
S105	Switch	SPPH2201	4A [HI/LOW]
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### [MAIN UNIT]

REF. NO.	DESCRIPTION	PART NO.
BT101	Lithium Battery	BR2325-1HC
W101	Wire	23/03/145/D21G/W01
W102	Wire	23/02/115/D21/W01
W103	Wire	23/04/040/W02/W02
W104	Wire	72/99/050/X98/X98
W105	Wire	23/01/130/D21/D21
W106	Wire	23/05/135/D21G/D21G
W107	Wire	23/06/090/D21/D21
W108	Wire	23/07/095/D21/D21
W109	Wire	23/08/100/D21/D21
W110	Wire	23/09/085/D21/D21
EP101	P.C. Board	B-1761B (MAIN)
EP102	P.C. Board	B-908 (P.C. Board)
EP103	F.P.C. Board	B-1045 (MAIN~LOGIC)
EP104	Ferrite Bead	DL2-OP2.6-3-1.2H
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### [PLL UNIT]

REF. NO.	DESCRIPTION	PART NO.
IC201	IC	SC-1030
IC202	IC	MB504P-G
IC203	IC .	μPD2834C
IC204	IC .	ND487C1-3R
Q201	Transistor	2SC2668 O
Q202	Transistor	2SC2026
Q203	Transistor	2SB888
Q204	Transistor	2SC2026
Q205	Transistor	2SC2407
Q206	Transistor	2SC2026
Q207	Transistor	2SC3586
Q208	Transistor	2SA1048 GR
Q209	Transistor	2SC2458 GR
Q211	Transistor	2SC2458 GR
Q212	Transistor	2SB909M R
Q213	Transistor	2SC2458 GR
Q214	Transistor	2SA1048 GR
Q215	Transistor	2SA1048 GR
Q216	Transistor	2SC2458 GR
Q217	Transistor	2SA1048 GR
Q218	FET	2SK184 GR
Q219	FET	2SK184 Y
Q220	Transistor	2SC2458 GR
Q221	Transistor	2SC2026
GZZ	Translator	2002020
D201	Diode	1SS254
D202	Diode	1SS254
D203	Diode	1SS265
D204	Diode	1SS265
D205	Diode	1SS254
D206	Diode	1SS97
D207	Diode	1SS97
D208	Diode	1SS265
D209	Diode	1SS265
D213	Varicap	1SV50E
D214	Zener	RD6.8 EB2
D215	Diode	1SS254
D216	Diode	1SS254
D219	Diode	1SS254
D221	Diode	1S953
D222	Diode	SLN-210MC
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### [PLL UNIT]

PEL ONIT			
REF. NO.	DESCRIPTION	PART NO.	
Fl201	Monolithic	30M7B (Narrow) 30M15B (Wide)	
FI202	rc	EXC-EMT103DC	
X201	Crystal	CR-270	
L201	Coil	LS-319	
L202 L204	Coil Coil	LS-320 LA-233	
L205	Coil	LA-126	
L206	Coil	LA-126	
L207 L208	Coil Coil	LA-232 LAL02TA R56M 0.56µ	
L209	Coil	LA-232	
L211	Coil	LA-147	
L212 L213	Coil   Coil	LA-232 LA-233	
L213	Coil	LAL02TA 100K 10μ	
L215	Coil	LAL03NA 4R7 4.7μ	
L216 L217	Coil Coil	LAL02TA 100K 10μ 5HW-44545A	
L217	Coil	LA-232	
L219	Coil	05M-3075	
L220 L221	Coil   Coil	LR-145 LR-145	
LZZI	Con	LN-145	
R201	Resistor	100 Ω ELR20	
R203	Resistor	100 Ω ELR20	
R204	Resistor	330 Ω ELR20	
R205 R206	Resistor Resistor	47 Ω ELR20 15 kΩ ELR20	
R207	Resistor	5.6 kΩ ELR20	
R208	Resistor	47 Ω ELR20 22 Ω ELR20	
R209 R213	Resistor Resistor	4.7 kΩ ELR20	
R214	Resistor	15 kΩ ELR20	
R215	Resistor	100 Ω ELR20 6.8 kΩ ELR20	
R216 R217	Resistor Resistor	10 kΩ ELR20	
R218	Resistor	22 kΩ ELR20	
R219 R220	Resistor Resistor	10 kΩ ELR20 1 kΩ ELR20	
R221	Resistor	1.2 kΩ ELR20	
R222	Resistor	220 Ω ELR20	
R223 R224	Resistor Resistor	560 Ω ELR20 47 Ω ELR20	
R225	Resistor	10 Ω ELR20	
R226	Resistor	18 kΩ ELR20	
R227 R228	Resistor Resistor	18 kΩ ELR20 100 Ω ELR20	
R229	Resistor	100 kΩ ELR20	
R230	Resistor	1.8 kΩ ELR20 6.8 kΩ ELR20	
R231 R232	Resistor Resistor	470 Ω ELR20	
R233	Resistor	6.8 kΩ ELR20	
R234	Resistor	1.5 kΩ ELR20 15 kΩ ELR20	
R238 R239	Resistor Resistor	15 kΩ ELR20 100 kΩ ELR20	
R241	Resistor	4.7 kΩ R20	
R242 R243	Resistor Resistor	10 kΩ R20 18 kΩ ELR20	
R245	Resistor	10 kΩ ELR20	
R246	Thermistor	33D28	
R247 R248	Thermistor Resistor	33D28 15 kΩ ELR20	
R248 R249	Resistor	10 kΩ ELR20	
R250	Resistor	6.8 kΩ ELR20	
R251 R252	Resistor Resistor	100 kΩ ELR20 100 kΩ ELR20	
R253	Resistor	2.2 kΩ ELR20	
R255	Resistor	100 kΩ ELR20	
R256	Resistor	100 Ω ELR20	

### [PLL UNIT]

### [PLL UNIT]

REF. NO.	DESCRIPTION	PART	NO.
R257	Resistor	1.8 kΩ	ELR20
R258	Resistor	560 kΩ	ELR20
R259	Resistor	22 kΩ	ELR20
R260 R261	Resistor Resistor	150 kΩ 82 kΩ	ELR20 ELR20
R262	Trimmer	62 KΩ 47 kΩ	RH0421CS4J08A
R263	Resistor	22 kΩ	ELR20
R264	Trimmer	47 kΩ	RH0421CS4J08A
R265 R266	Resistor Resistor	2.2 kΩ 8.2 kΩ	ELR20 ELR20
R267	Resistor	0.2 KΩ 10 kΩ	ELR20
R268	Thermistor	112503-2A	I
R269	Resistor	47 kΩ	ELR20
R270 R271	Resistor Resistor	1 MΩ 5.6 kΩ	ELR20 ELR20
R272	Resistor	47 kΩ	ELR20
R273	Resistor	27 Ω	ELR20
R274	Resistor	47 kΩ	ELR20
R275 R276	Resistor Resistor	220 Ω 47 Ω	ELR20 ELR20
R278	Resistor	1 kΩ	ELR20
R279	Resistor	22 kΩ	ELR20
R280	Resistor	10 kΩ	ELR20
R281 R282	Resistor Resistor	4.7 kΩ 220 Ω	ELR20 R20
R283	Resistor	2.2 MΩ	ELR20
R284	Resistor	150 Ω	ELR20
R285	Resistor	4.7 kΩ	R20
R286 R287	Resistor Resistor	220 kΩ 270 kΩ	R20 ELR20
R288	Resistor	100 kΩ	ELR20
R290	Resistor	100 kΩ	ELR20
R291	Resistor	10 kΩ	ELR20
R292 R293	Resistor Resistor	22 kΩ 10 kΩ	ELR20 R20
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C201	Ceramic	470 pF	50 V
C202 C203	Ceramic Ceramic	10 pF 0.001 μF	50 V 50 V
C204	Ceramic	0.001 μF	50 V
C205	Barrier Layer	0.01 μF	25 V
C206	Ceramic	22 pF 27 pF	50 V 50 V (Narrow)
C207	Ceramic	27 pr 12 pF	50 V (Warrow)
C208	Barrier Layer	0.01 μF	25 V
C209	Barrier Layer	0.0047 μF	25 V
C210	Ceramic	120 pF	50 V 50 V
C211 C212	Ceramic Ceramic	47 pF 68 pF	50 V
C213	Ceramic	0.001 μF	50 V
C216	Barrier Layer	0.0015 μF	25 V
C217 C218	Ceramic Ceramic	8 pF 0.001 μF	50 V 50 V
C218 C219	Ceramic Ceramic	0.001 μF 0.001 μF	50 V
C220	Ceramic	6 pF	50 V
C221	Ceramic	470 pF	50 V
C222 C224	Ceramic Ceramic	470 pF 0.001 μF	50 V 50 V
C224 C225	Ceramic	0.001 μF 4 pF	50 V 50 V
C226	Ceramic	0.001 μF	50 V
C227	Ceramic	0.001 μF	50 V
C228 C229	Ceramic Ceramic	470 pF 12 pF	50 V 50 V
C229 C230	Ceramic	0.001 μF	50 V
C231	Ceramic	47 pF	50 V
C232	Ceramic	47 pF	50 V
C233 C234	Ceramic Ceramic	0.001 μF 6 pF	50 V 50 V
C234 C235	Ceramic	0 рг 10 pF	50 V
C236	Ceramic	47 pF	50 V
C237	Ceramic	47 pF	50 V
C238 C239	Ceramic Ceramic	0.001 μF 36 pF	50 V 50 V
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REF. NO.	DESCRIPTION	PART	NO.
C240	Ceramic	0.001 μF	50 V
C241	Ceramic	82 pF	50 V
C242 C243	Ceramic Ceramic	18 pF 10 pF	50 V 50 V
C243	Ceramic	12 pF	50 V
C245	Ceramic	6 pF	50 V
C246	Ceramic	6 pF	50 V
C247	Ceramic	33 pF	50 V
C248	Ceramic Ceramic	47 pF 47 pF	50 V 50 V
C249 C253	Ceramic	47 pF 470 pF	50 V
C254	Ceramic	2 pF	50 V
C255	Ceramic	0.001 μF	50 V
C256	Ceramic	10 pF	50 V
C257 C258	Ceramic Tantalum	0.1 μF 0.1 μF	D33Y5V1E104Z21 35 V DN
C259	Ceramic	0.001 μF	50 V
C260	Ceramic	47 pF	50 V
C261	Ceramic	47 pF	50 V
C262	Ceramic	47 pF	50 V
C265 C267	Electrolytic Tantalum	10 μF 22 μF	16 V RC3 16 V DN
C268	Ceramic	0.001 μF	
C269	Trimmer	15 pF	ECRGA015E30
C270	Ceramic	33 pF	50 V CH
C271	Ceramic Ceramic	4 pF 0.001 μF	50 V CH 50 V
C272 C274	Ceramic Ceramic	0.001 μF 220 pF	50 V 50 V
C275	Ceramic	100 pF	50 V
C276	Barrier Layer	0.01 μF	25 V
C277	Tantalum	10 μF	16 V DN
C279	Ceramic	47 pF 47 pF	50 V 50 V
C280 C281	Ceramic Ceramic	47 pF	50 V
C283	Ceramic	470 pF	50 V
C284	Ceramic	470 pF	50 V
C285	Ceramic	47 pF	50 V
C287 C288	Ceramic Electrolytic	470 pF 22 μF	50 V 6.3 V RC2
C289	Ceramic	470 pF	50 V
C290	Ceramic	470 pF	50 V
C292	Ceramic	470 pF	50 V
C293 C294	Ceramic Electrolytic	0.001 μF 100 μF	50 V 6.3 V RC2
C294 C296	Ceramic	47 pF	50 V
C297	Ceramic	47 pF	50 V
C299	Ceramic	47 pF	50 V
C300	Ceramic	0.1 μF	D33Y5V1E104Z21
C302 C304	Ceramic Tantalum	0.001 μF 0.1 μF	50 V 35 V DN
C308	Ceramic	0.001 μF	50 V
C309	Ceramic	7 pF	50 V
C311	Ceramic	47 pF	50 V
C312	Ceramic Ceramic	0.001 μF 0.001 μF	50 V 50 V
C313 C314	Ceramic Ceramic	0.001 μF 0.1 μF	D33Y5V1E104Z21
C315	Barrier Layer	0.01 μF	25 V
C316	Ceramic	470 pF	50 V
C317	Ceramic	0.1 μF	D33Y5V1E104Z21 35 V DN
C318 C319	Tantalum Ceramic	6.8 μF 3 pF	50 V
C320	Ceramic	47 pF	50 V
C321	Ceramic	0.1 μF	D33Y5V1E104Z21
C322	Tantalum	10 μF	6.3 V CS
J201	Connector	TNC-102-N	
J202	Connector	HSJ0836-0	
J203 J204	Connector Connector	HSJ1102-0 HEC0747-0	
J204 J205	Connector	171255-1	J. 310
J206	Connector	171255-1	

### [PLL UNIT]

REF. NO.	DESCRIPTION	PART NO.
W201 W202 W203 W204 W205	Shield Cable Shield Cable Jumper	(66/99/115/W99/W99) 08 (66/99/040/W18/W18) 08 JPW-01 R01
W206 W207 W208 W209 W210 W211 W212 W213 W214 W215 W216	Wire Jumper Wire Jumper Jumper Wire Wire Wire Wire Jumper Jumper Jumper	72/98/015/X98/X98 JPW-01 R01 72/98/010/X98/X98 JPW-01 R01 JPW-01 R01 72/98/010/X98/X98 72/98/010/X98/X98 72/98/010/X98/X98 23/03/080/W02/W02 JPW-01 R01 JPW-01 R01
EP201 EP202 EP203 EP204 EP212 EP215 EP217 EP218	P.C. Board Ferrite Bead Ferrite Bead Ferrite Bead Ferrite Bead F.P.C. Board F.P.C. Board F.P.C. Board	B-1674B DL2-OP2.6-3-1.2H DL2-OP2.6-3-1.2H DL2-OP2.6-3-1.2H DL2-OP2.6-3-1.2H B-1044 (PLL~MAIN) B-1147 (PA shield) DL2-OP2.6-3-1.2H

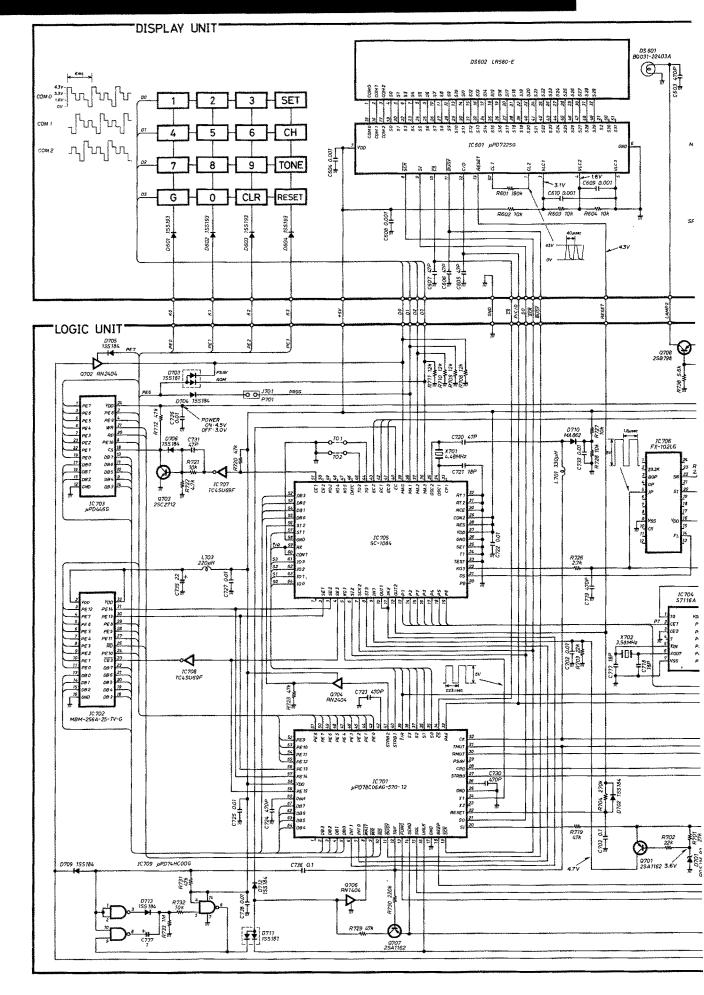
### [VCO UNIT]

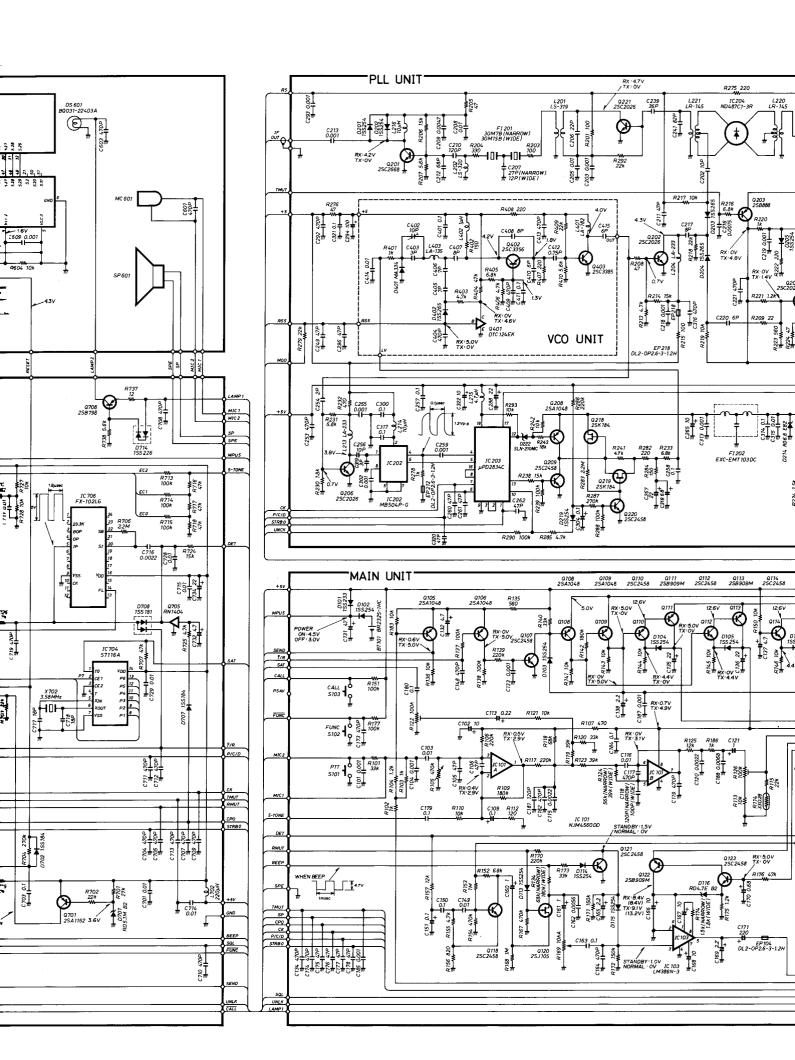
REF. NO.	DESCRIPTION	PART	r NO.	
Q401	Transistor	DTC124EK		
Q402	Transistor	2SC3356		
Q403	Transistor	2SC3585		
D401	Varicap	MA334		
D402	Diode	1SS265		
L401	Coil	LA-182		
L402	Coil	LQN5N1R0M 1μ		
L402	Coil	LA-135		
1400	00,11	271 100		
R401	Resistor	1 kΩ	R20	
R402	Resistor	150 Ω	MCR10	
R403	Resistor	4.7 kΩ	MCR10	
R404	Resistor	47 kΩ	MCR10	
R405	Resistor	6.8 kΩ	MCR10	
R406	Resistor	4.7 kΩ	MCR10	
R407	Resistor	220 Ω	MCR10	
R408	Resistor	220 Ω	MCR10	
R409	Resistor	22 kΩ	MCR10	
R410	Resistor	5.6 kΩ	MCR10	
1				
C401	Ceramic	0.1 μF	D33Y5V1E104Z21	
C402	Trimmer	10 pF	TZB04N100BA	
C403	Ceramic	3 pF	GRM40	
C404	Ceramic	470 pF	GRM40	
C405	Ceramic	7 pF	GRM40	
C406	Ceramic	7 pF	GRM40	
C407	Ceramic	8 pF	GRM40	
C408	Ceramic	8 pF	GRM40	
C409	Ceramic	470 pF	GRM40	
C410	Ceramic	6 pF	GRM40	
C411	Ceramic	0.1 μF	GRM40 F	

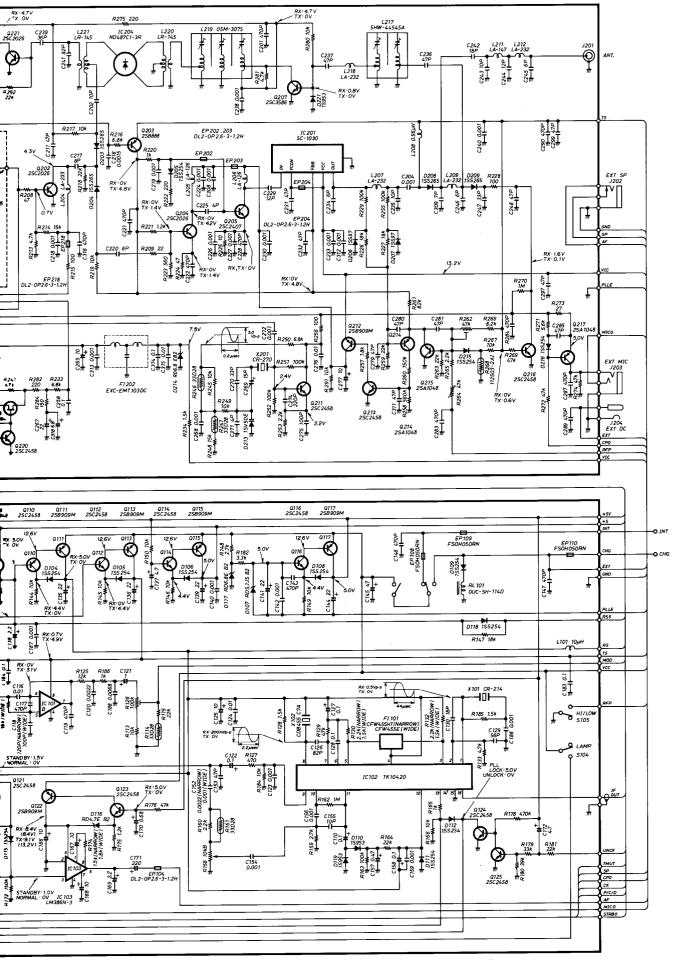
### [VCO UNIT]

255 110		DARI	, NO
REF. NO.	DESCRIPTION		
C412 C413	Ceramic Ceramic	0.75 pF 470 pF	GRM40 GRM40 GRM40 F 50 V
C414	Ceramic	0.01 μF	GRM40 F
C415	Ceramic	6 pF	50 V
EP401	P.C. Board	B-1762	
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# SECTION 9 VOLTAGE DIAGRAM







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